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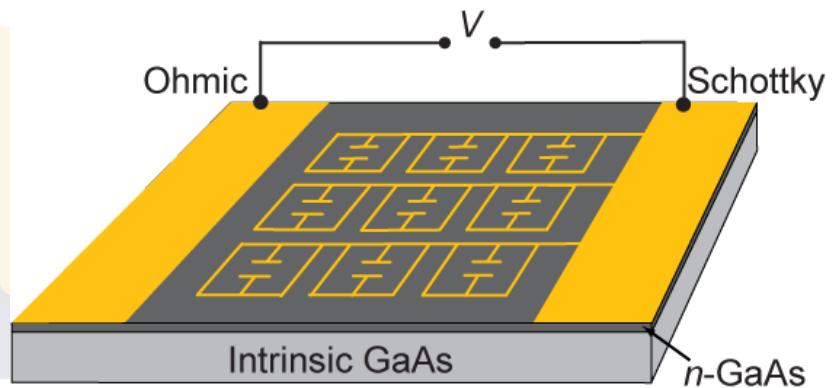
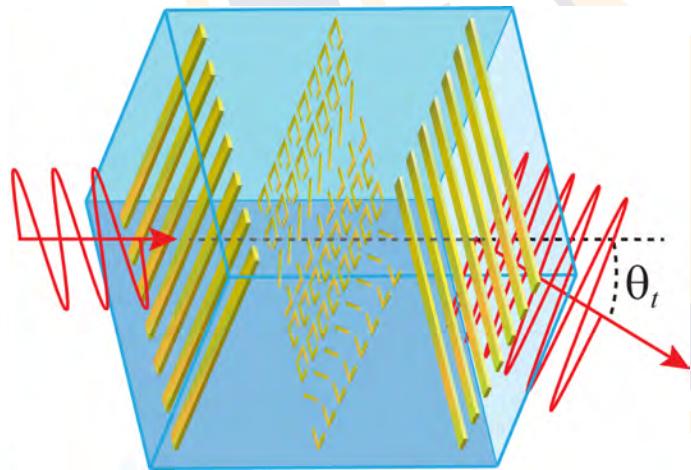
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Seminar @ University of Notre Dame  
March 20, 2015

# Applying Metamaterials to Solve Terahertz Challenges

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Los Alamos National Laboratory*





## Center for Nanoscale Materials Argonne National Laboratory

### Molecular Foundry Lawrence Berkeley National Laboratory



### Center for Functional Nanomaterials Brookhaven National Laboratory



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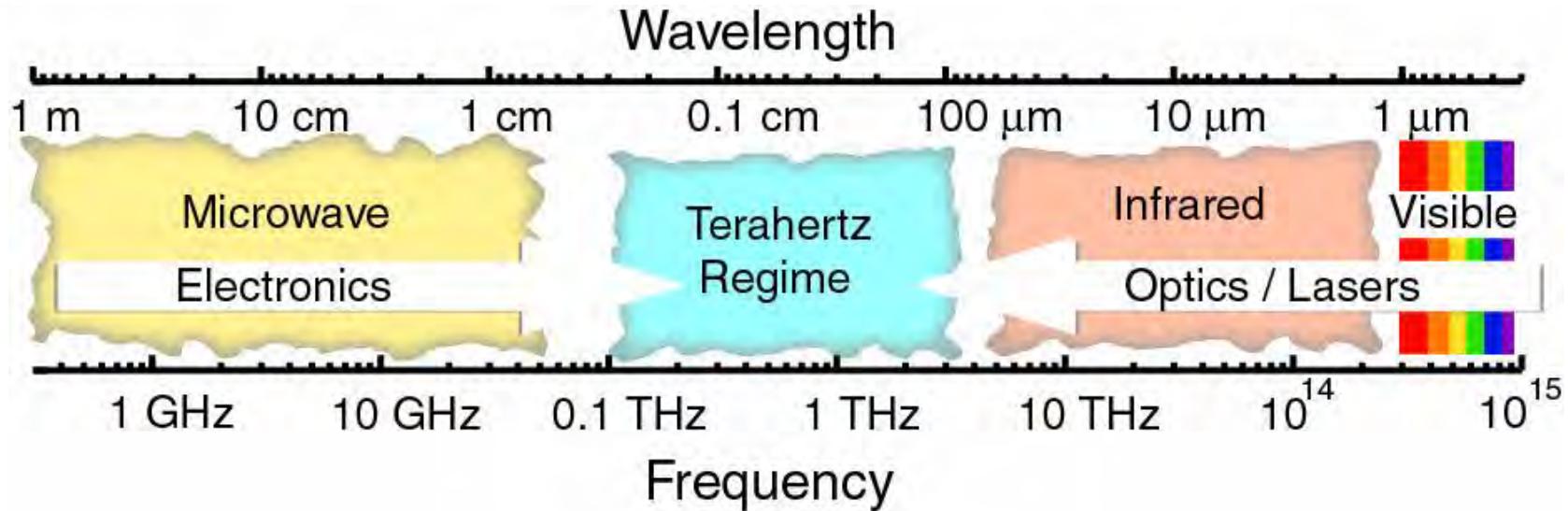
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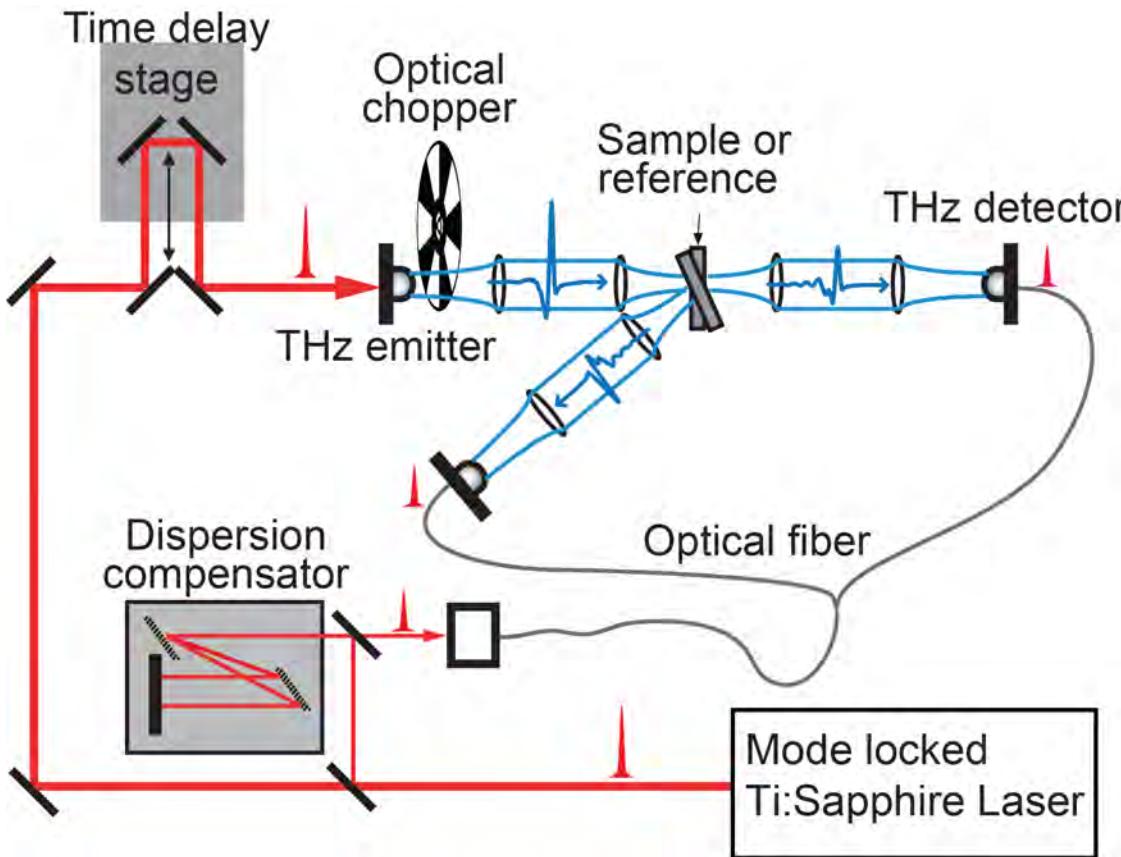
# Challenges in THz Science and Technology



- THz is one of the least developed and most challenging regimes in the electromagnetic spectrum
- Functional THz devices and components are not widely available
- Metamaterials provide excellent opportunities in solving the material challenges associated with the “THz gap”

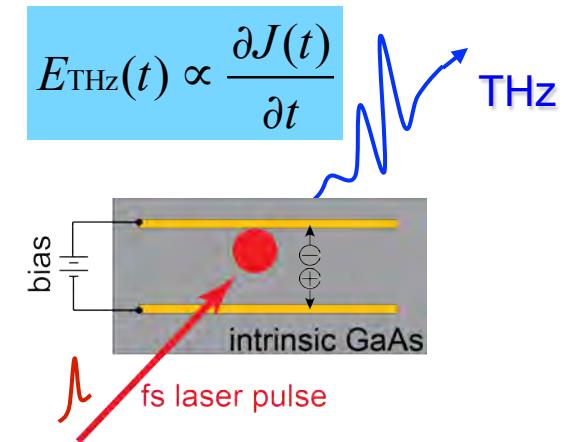
# Terahertz Generation and Detection

## Schematic of a THz time-domain spectrometer

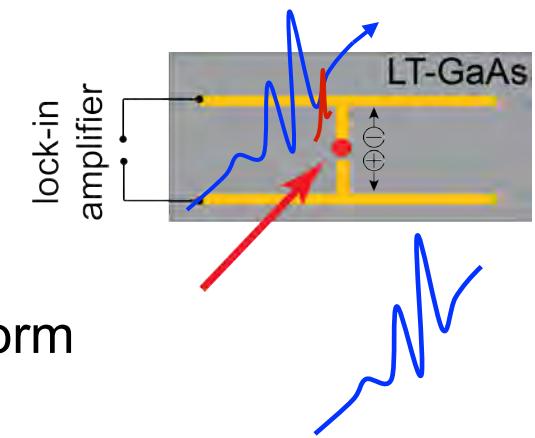


Measure the THz pulse waveform  
 in the time-domain

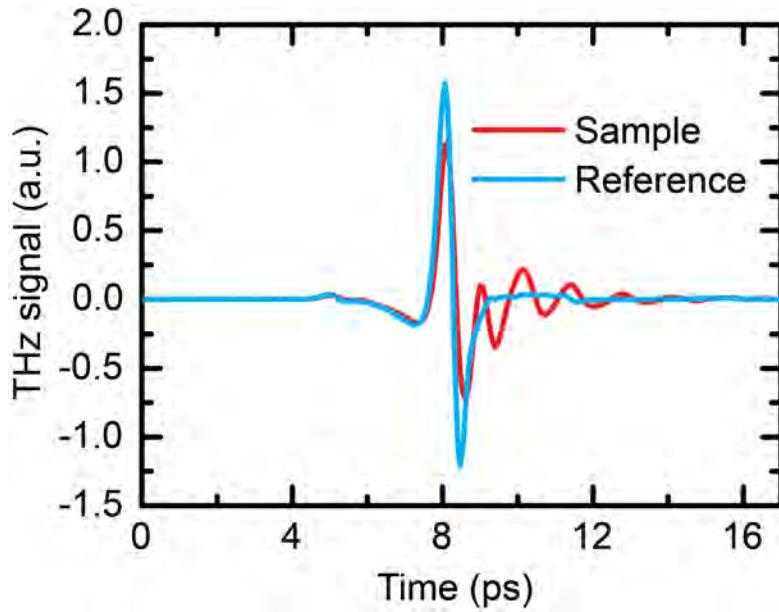
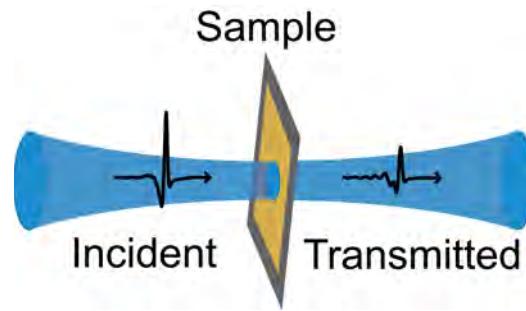
## THz generation:



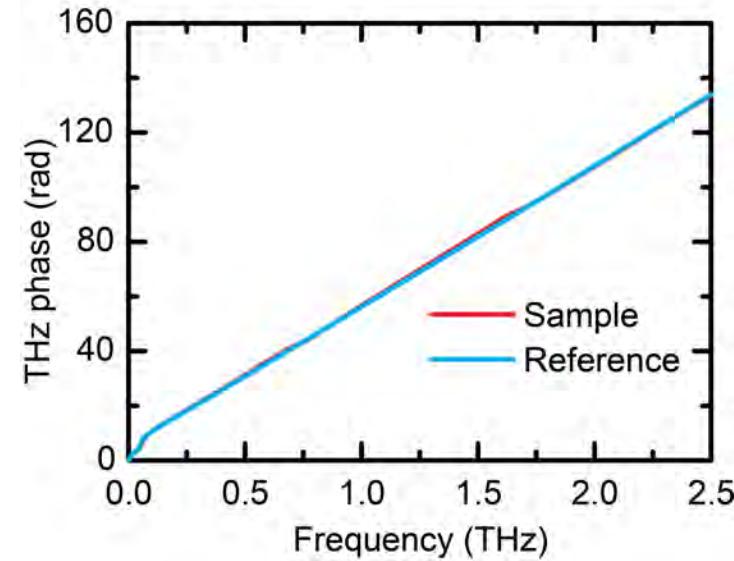
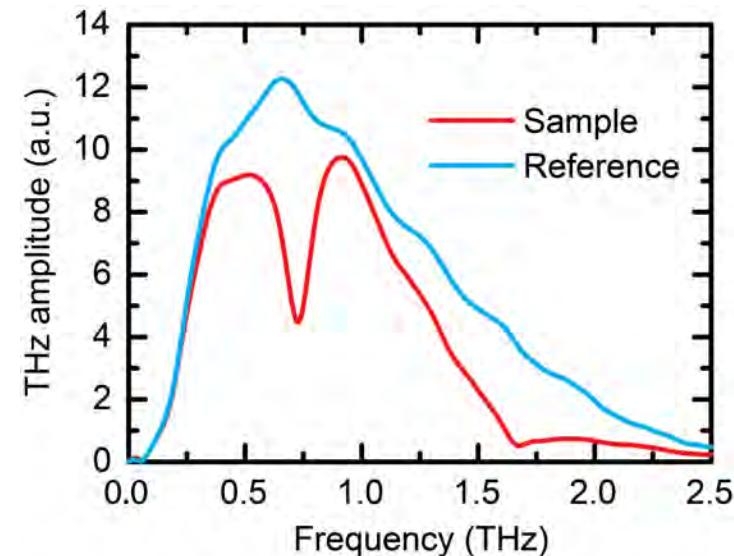
## THz-detection:



# Terahertz Time-Domain Spectroscopy



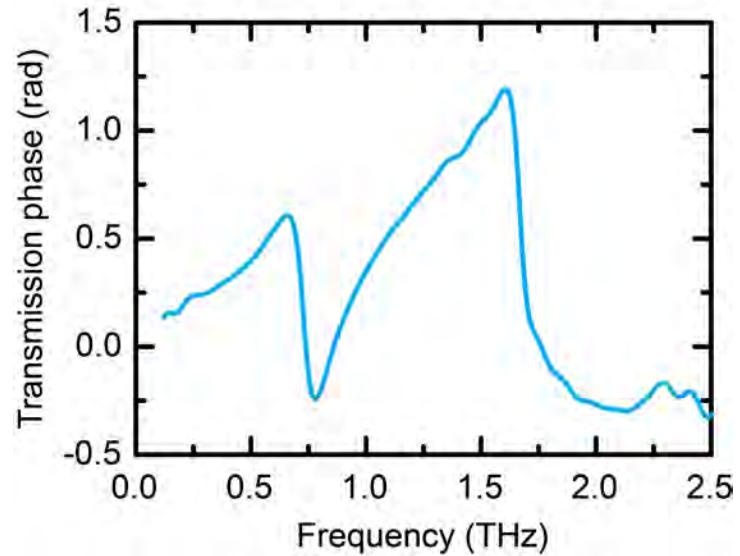
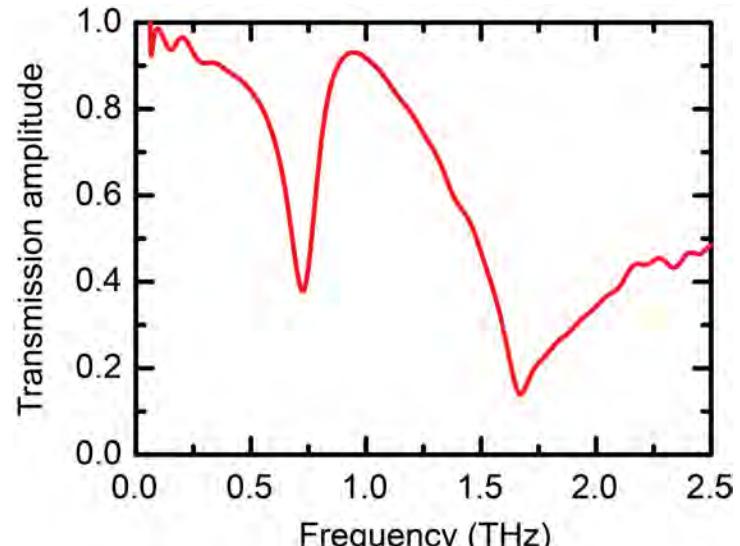
FFT



# Terahertz Time-Domain Spectroscopy

$$\tilde{t}(\omega) = \frac{E_{\text{Sam}}(\omega)}{E_{\text{Ref}}(\omega)}$$

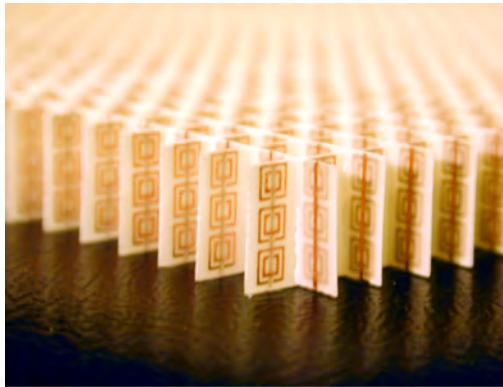
- Obtain simultaneously the amplitude and phase information
- To extract complex dielectric function  $\epsilon(\omega)$  over a broad frequency range (non-magnetic materials)
- Reflection measurement is also required to further extract the complex permeability  $\mu(\omega)$  for materials with magnetic response



# Bulk Metamaterials vs Meta-Surfaces

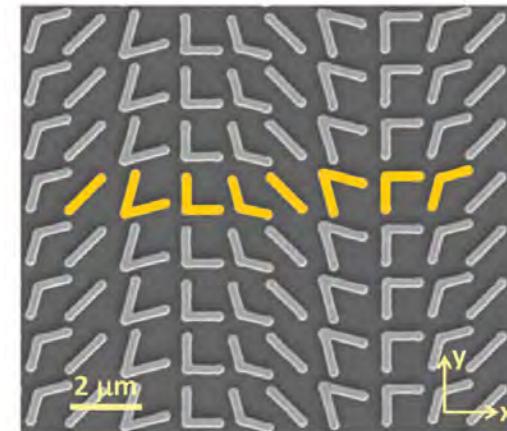
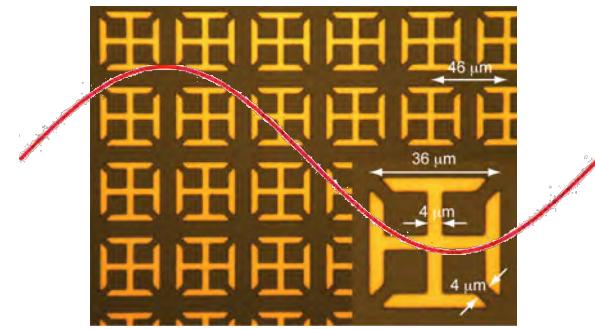
## Bulk metamaterials

- Effective material parameters:  $\epsilon$ ,  $\mu$ ,  $n$ ,  $Z$
- Difficult to fabricate in the optical regime
- High loss and narrow bandwidth issues



## Meta-surfaces

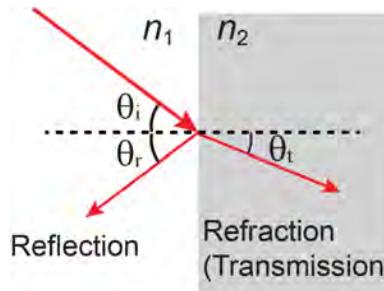
- Interface properties
- Planar structures: ease in fabrication
- Limited interaction with EM waves



# Tailored Reflection and Transmission at Meta-Surfaces

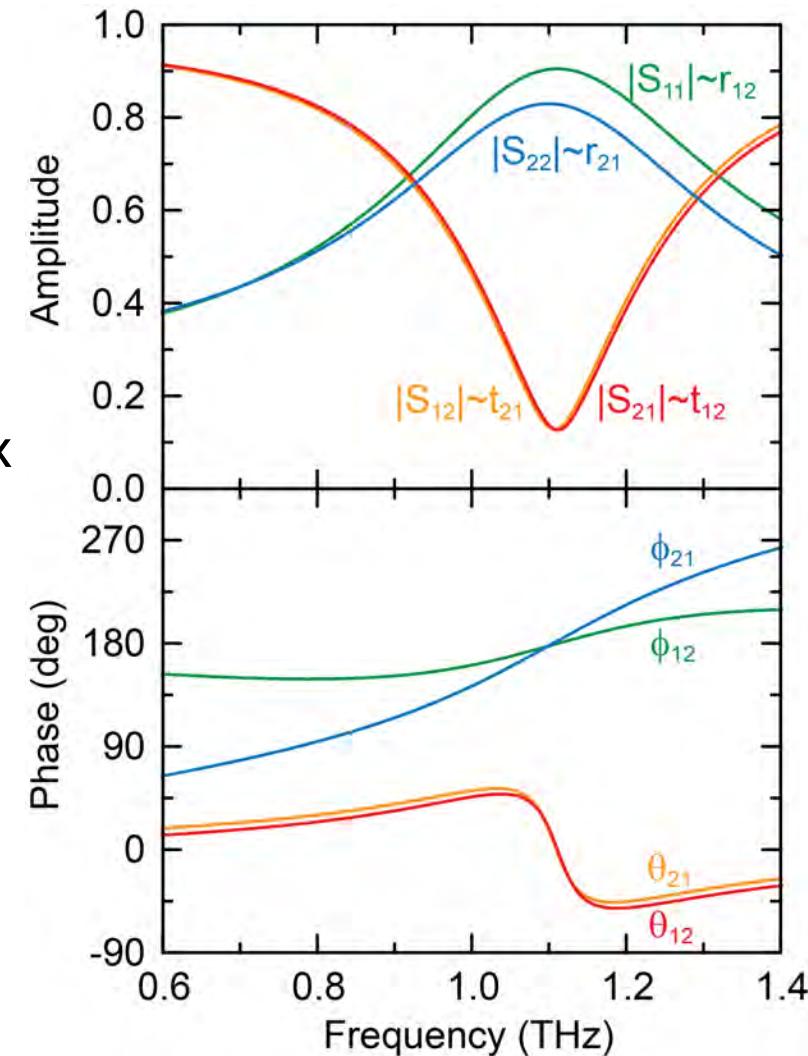
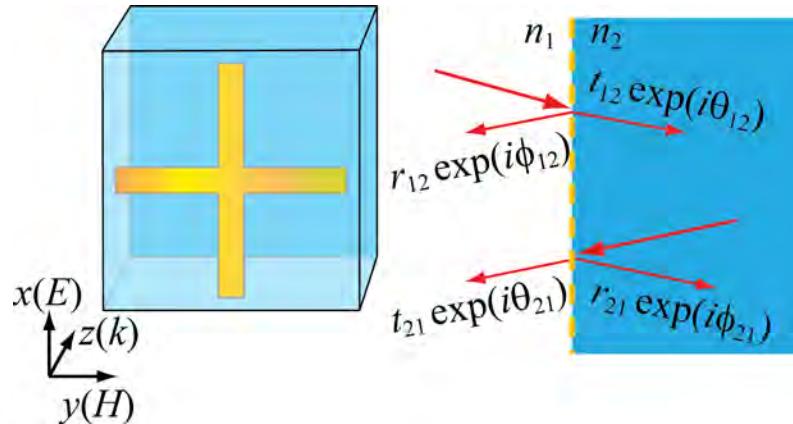
- For a bare dielectric surface:

$$r = \frac{n_1 - n_2}{n_1 + n_2} \quad t = \frac{2n_1}{n_1 + n_2}$$

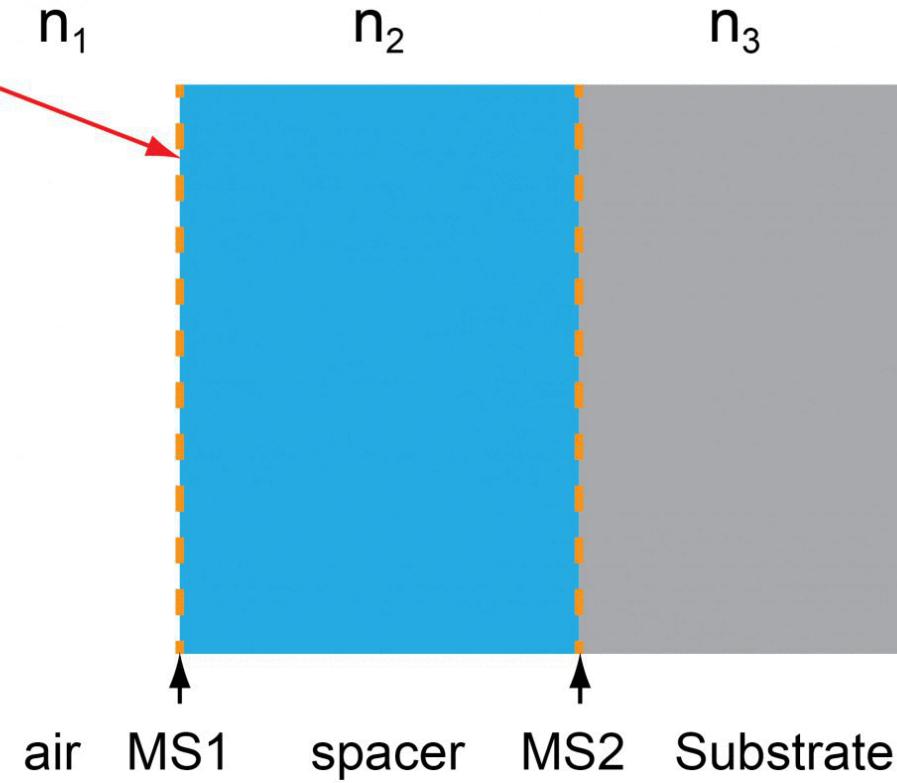


at normal incidence  
with constant values

- The resonator array modifies the complex reflection and transmission coefficients with **strong dispersion** at the interface



# Interference in Few-Layer Metamaterials

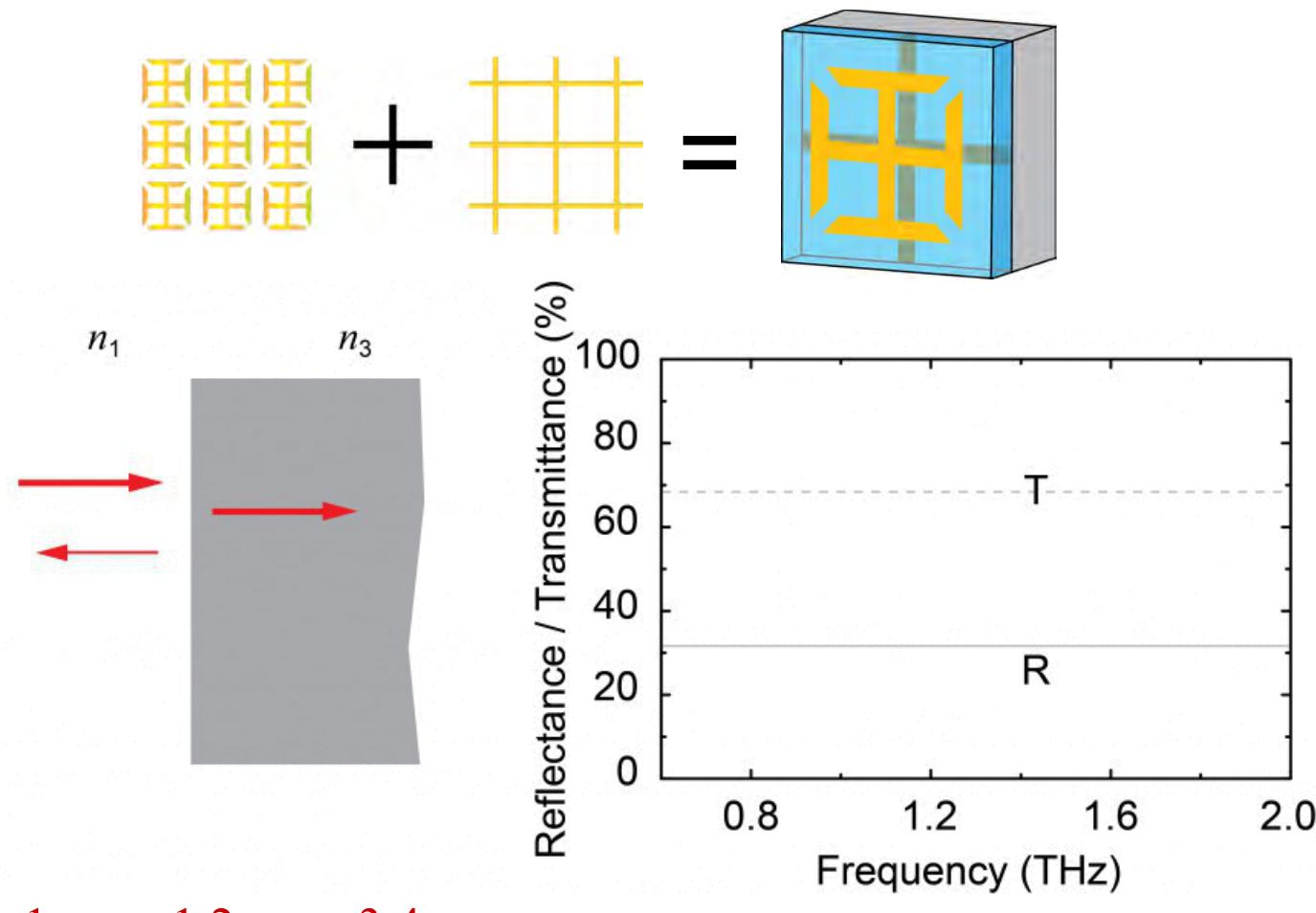


$$\tilde{r} = \tilde{r}_{12} + \frac{\tilde{t}_{12}\tilde{t}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}{1 - \tilde{r}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}$$

$$\tilde{t} = \frac{\tilde{t}_{12}\tilde{t}_{23}e^{i\tilde{\beta}}}{1 - \tilde{r}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}$$

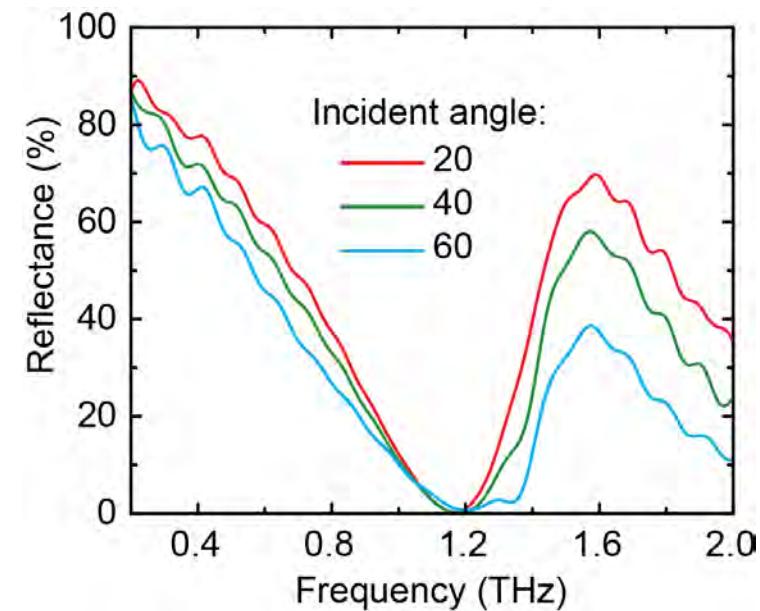
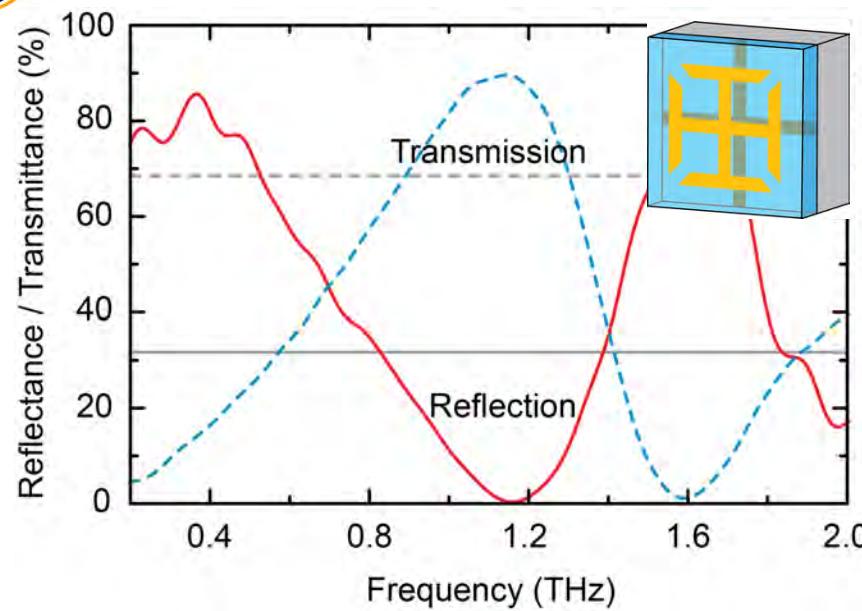
Chen, *Opt. Express* **20**, 7165 (2012).

# Ultrathin Bi-Layer Metasurface Antireflection Coatings



Chen *et al.*, *Phys. Rev. Lett.* **105**, 073901 (2010).

# Ultrathin Bi-Layer Metasurface ARC: Experiments



## ☐ Structure:

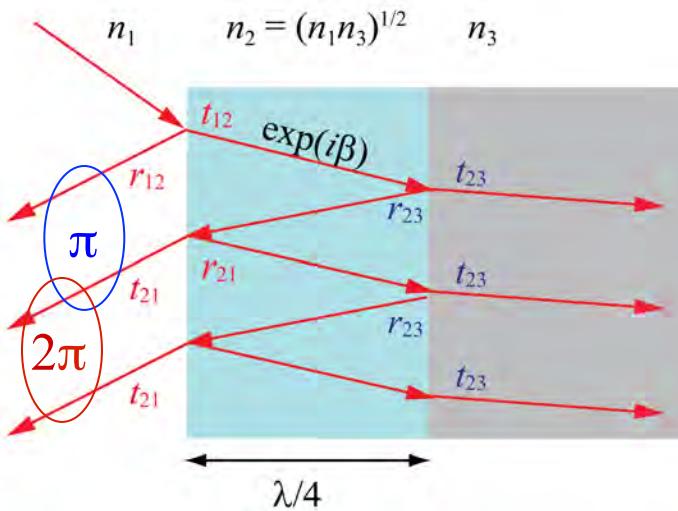
- Period (46  $\mu\text{m}$ ); gold width (4  $\mu\text{m}$ ); SRR outer dimension (36  $\mu\text{m}$ ); gold thickness (200 nm); gap (4  $\mu\text{m}$ )
- Polyimide spacer thickness ( $\sim$ 13  $\mu\text{m}$ ), dielectric constant ( $\sim$ 3), loss tangent: ( $\sim$ 5%)

## ☐ Performance:

- Reflectance: 32%  $\rightarrow$   $\sim$ 0
- Transmittance: 68%  $\rightarrow$  90%
- Wide incidence angle range
- No requirement of index matching

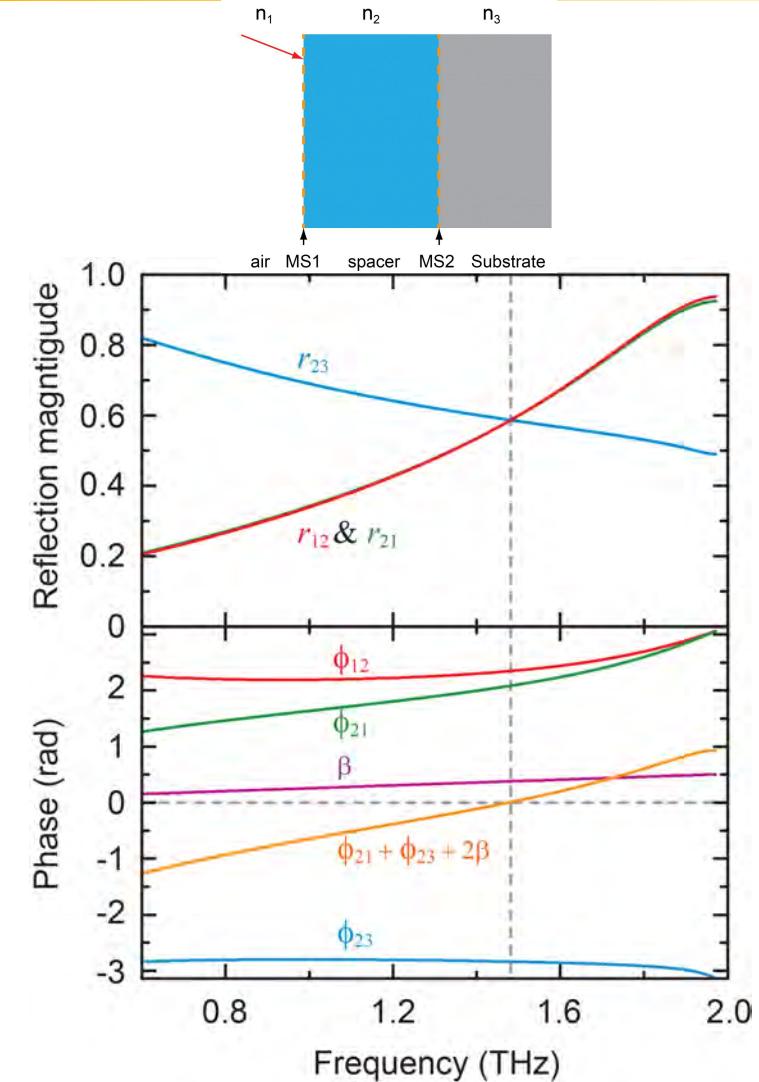
# Mechanism of Metamaterial Antireflection

## □ Quarter-wave antireflection:



## ☐ Metasurface antireflection:

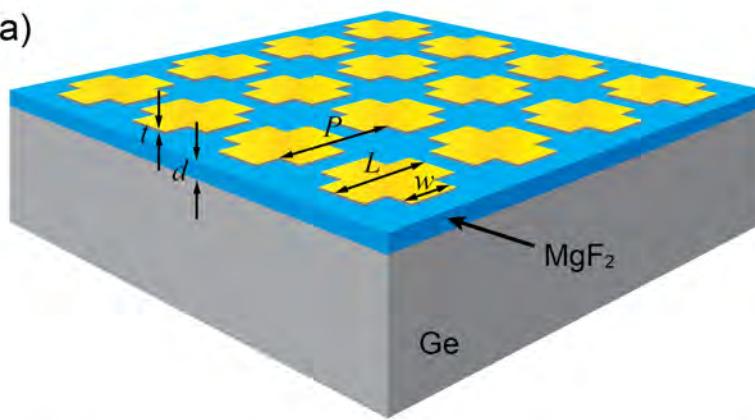
- $r_{12} = r_{21} = r_{23}$
- $\theta_{12} + \phi_{23} + \theta_{21} + 2\beta - \phi_{12} = \pi$
- $\phi_{21} + \phi_{23} + 2\beta = 0$



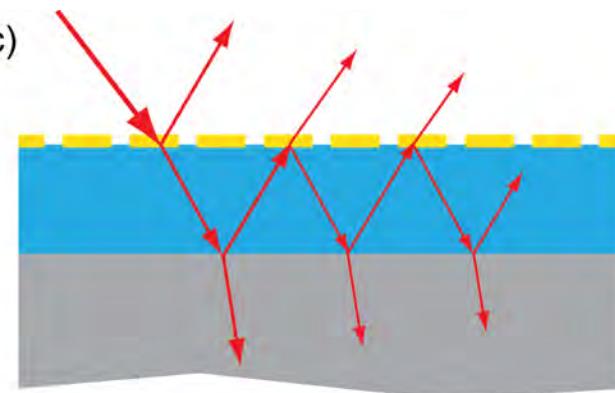
Chen *et al.*, *Phys. Rev. Lett.* **105**, 073901 (2010).

# Single-Layer Metasurface ARC in MIR

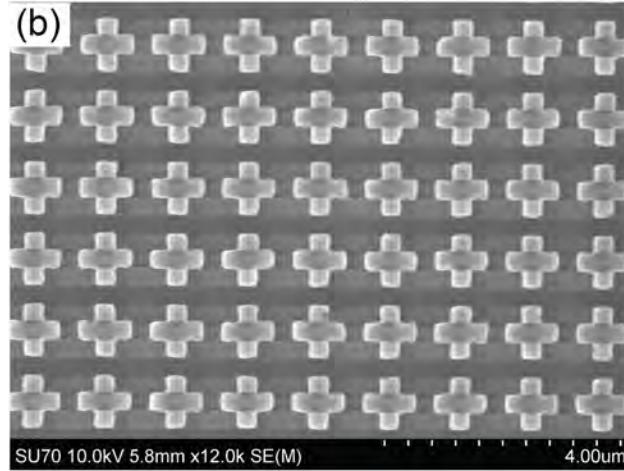
(a)



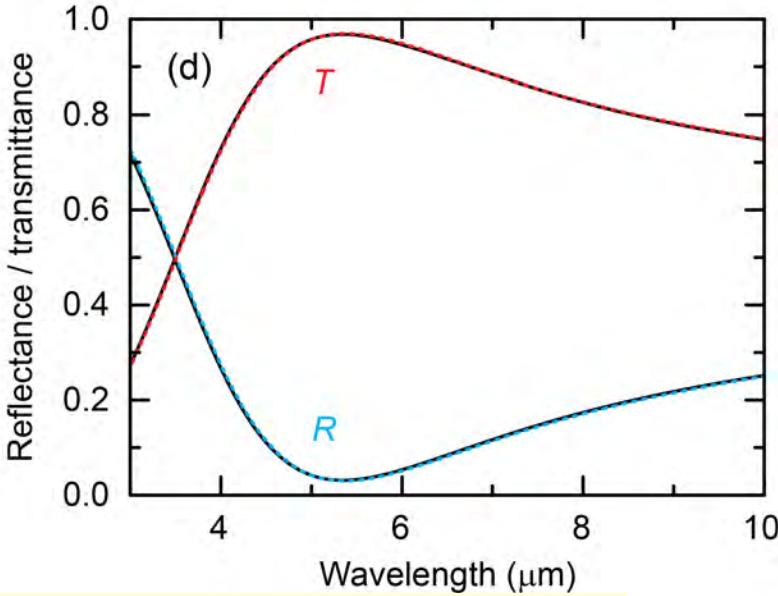
(c)



(b)

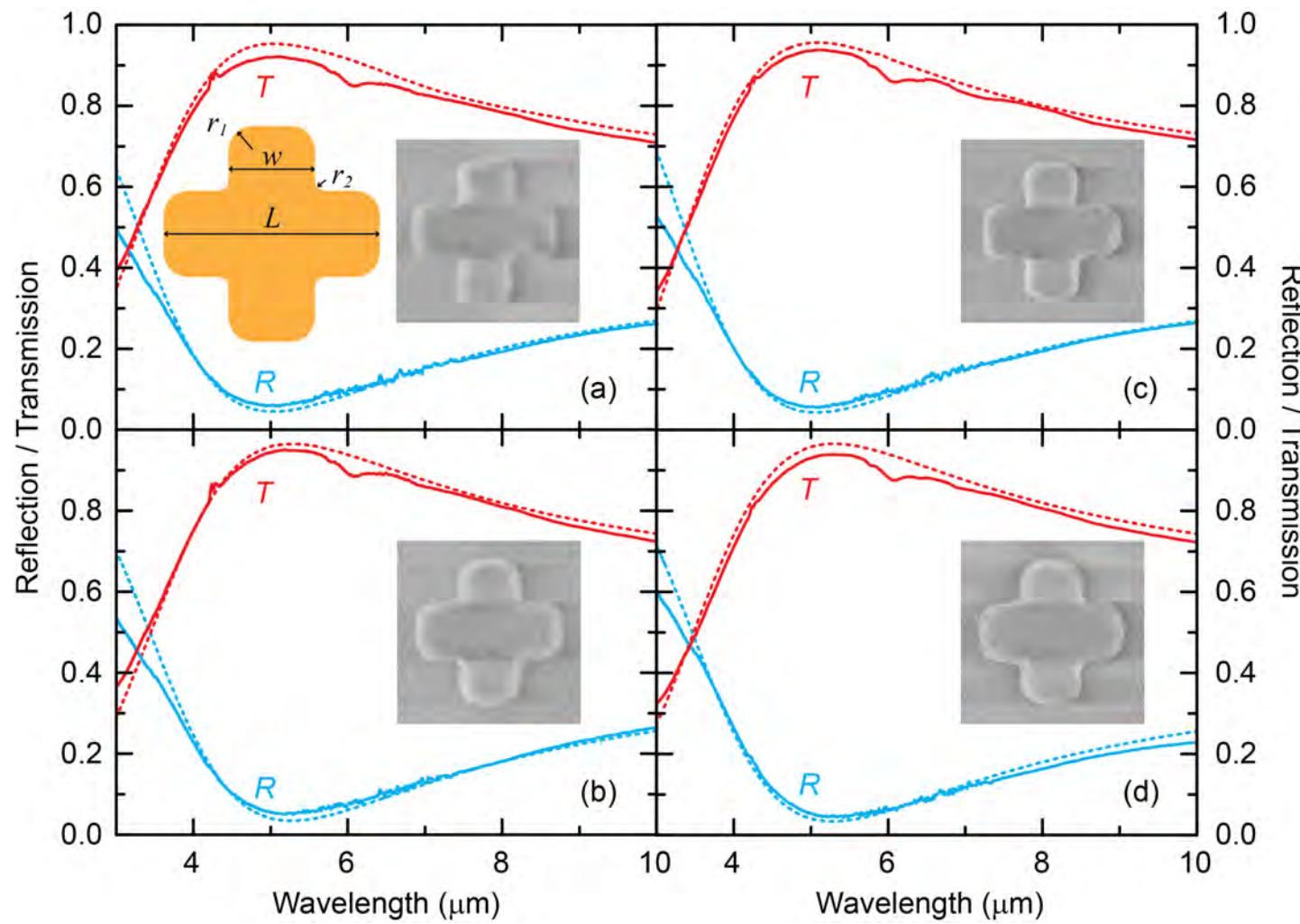


Reflectance / transmittance

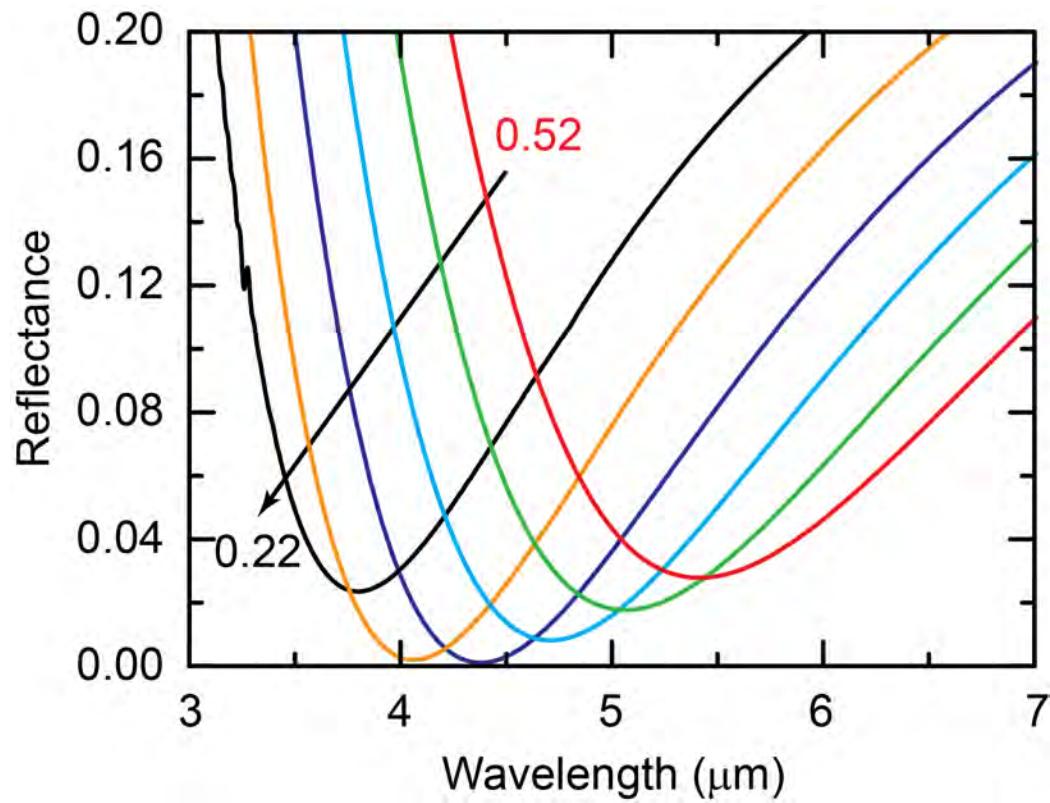


Zhang *et al.*, *Appl. Phys. Lett.* **105**, 241113 (2014).

# Single-Layer Metasurface ARC in MIR



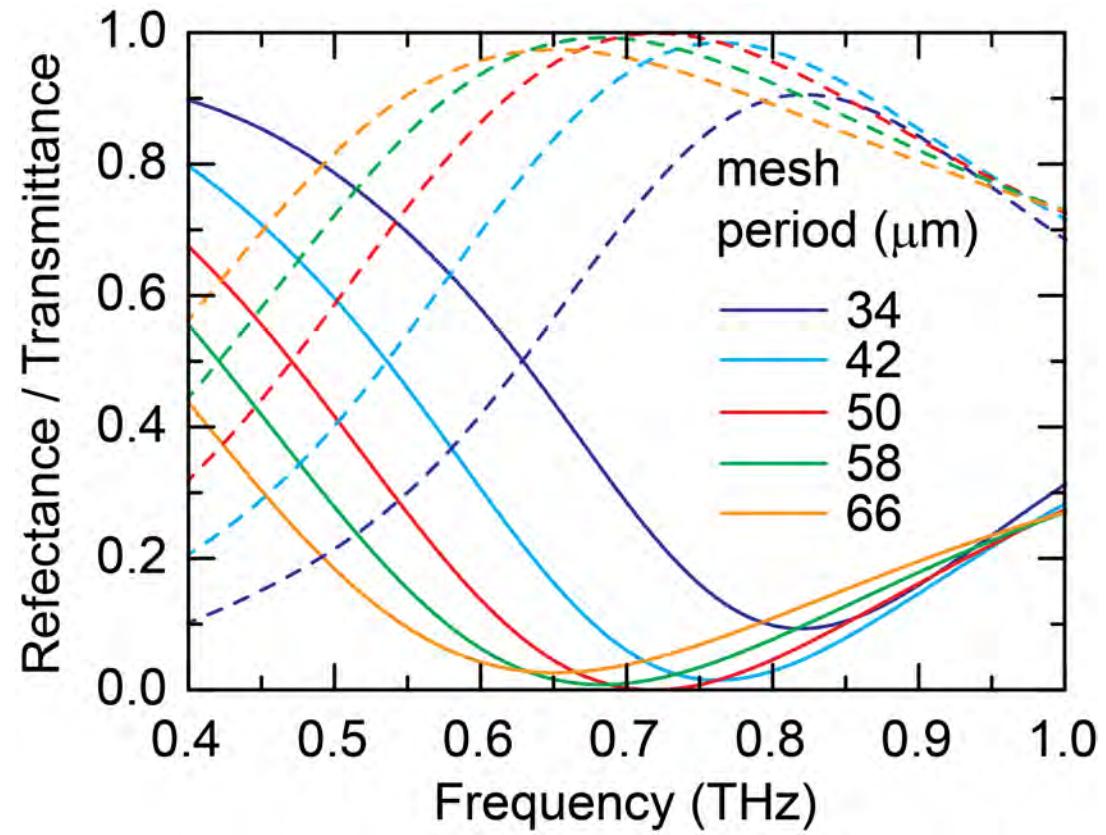
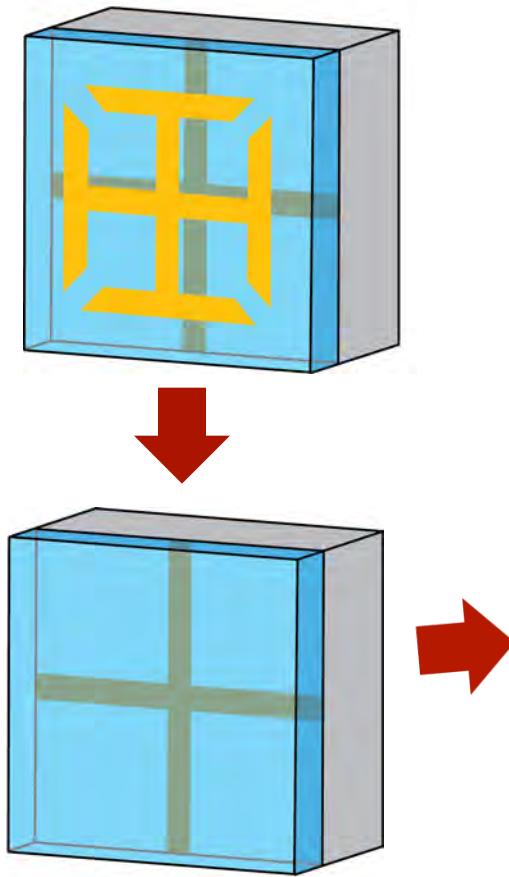
# Spacer Thickness Dependence



- ❑ The spacer thickness (520 nm) is too much in our experiments
- ❑ The optimized spacer thickness is  $\sim$ 320 nm

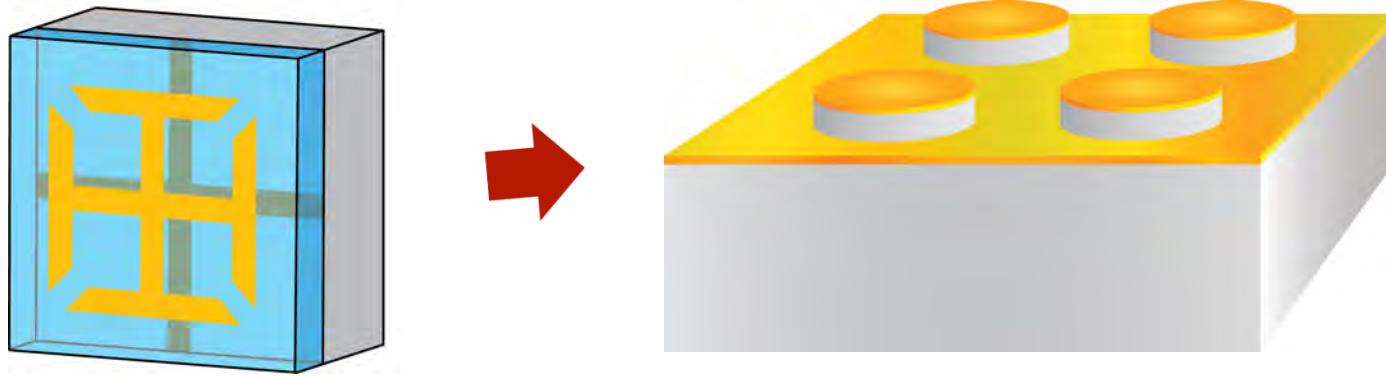
Zhang *et al.*, *Appl. Phys. Lett.* **105**, 241113 (2014).

# Laminating Silicon on Metal Mesh as ARC



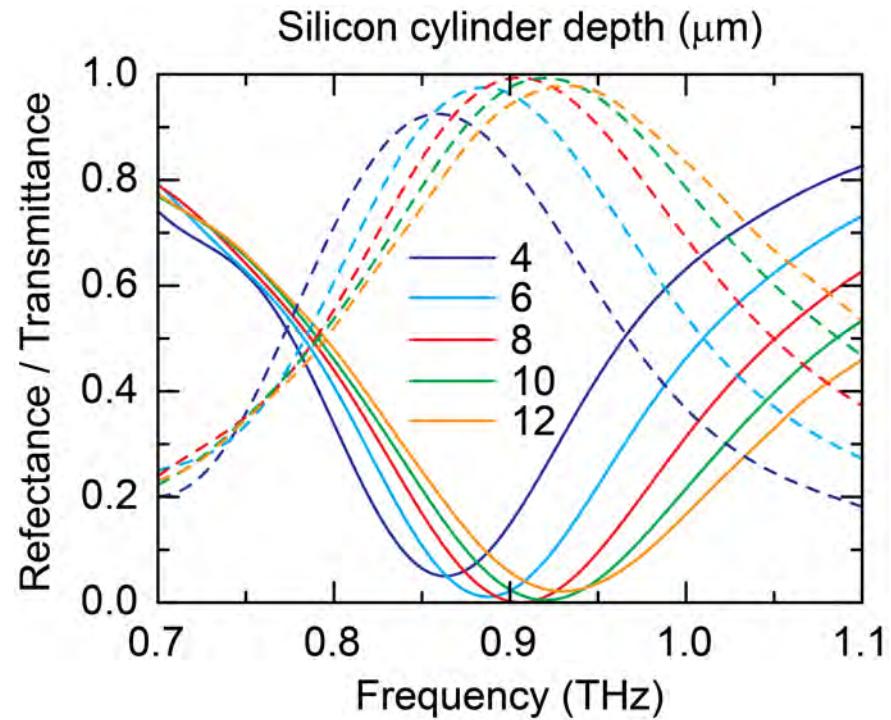
- Define metal mesh on top of the silicon substrate
- Lamine thin silicon superstrate ( $\sim 20 \mu\text{m}$  thick)

# Metal-Coated Silicon Pillar Array for ARC

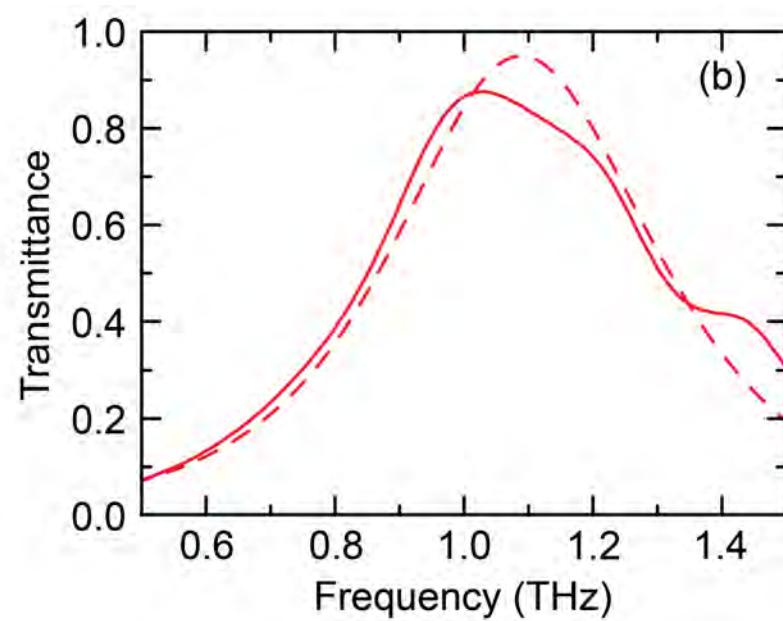
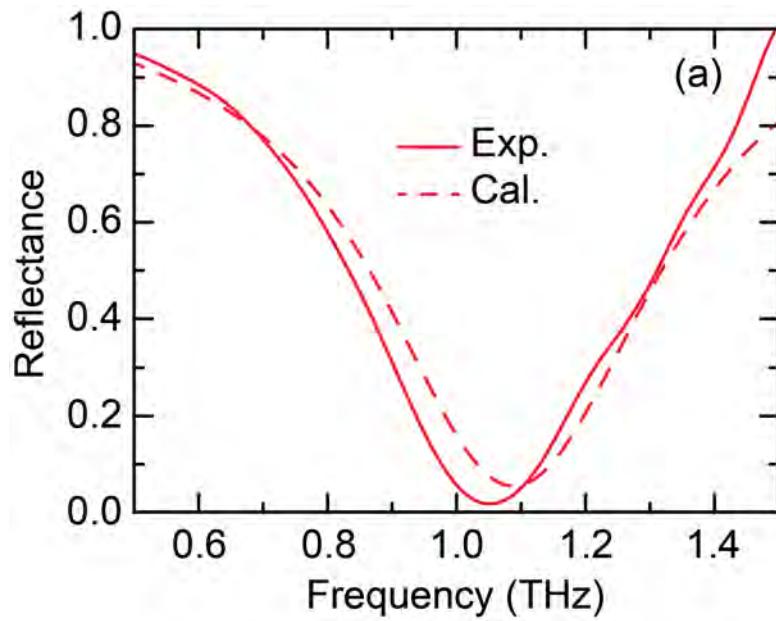
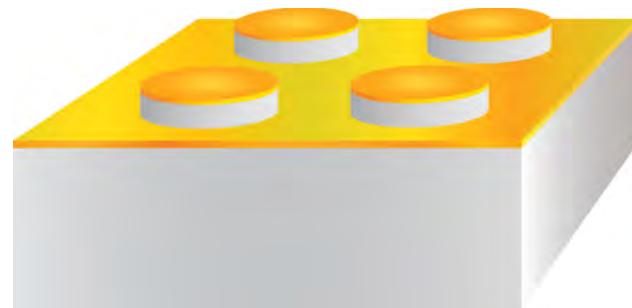


## ❑ Fabrication:

- Photolithography to define the cylinders (diameter~50  $\mu\text{m}$ , period~60  $\mu\text{m}$ )
- RIE to form the silicon cylinders (~8  $\mu\text{m}$  depth)
- (Directional) metal deposition (200 nm gold)

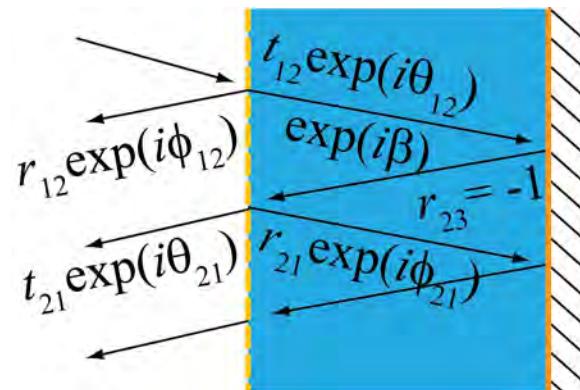
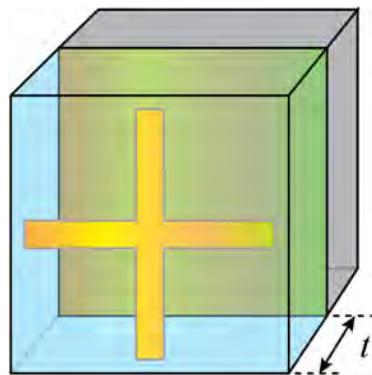


# Metal-Coated Silicon Pillar Array for ARC



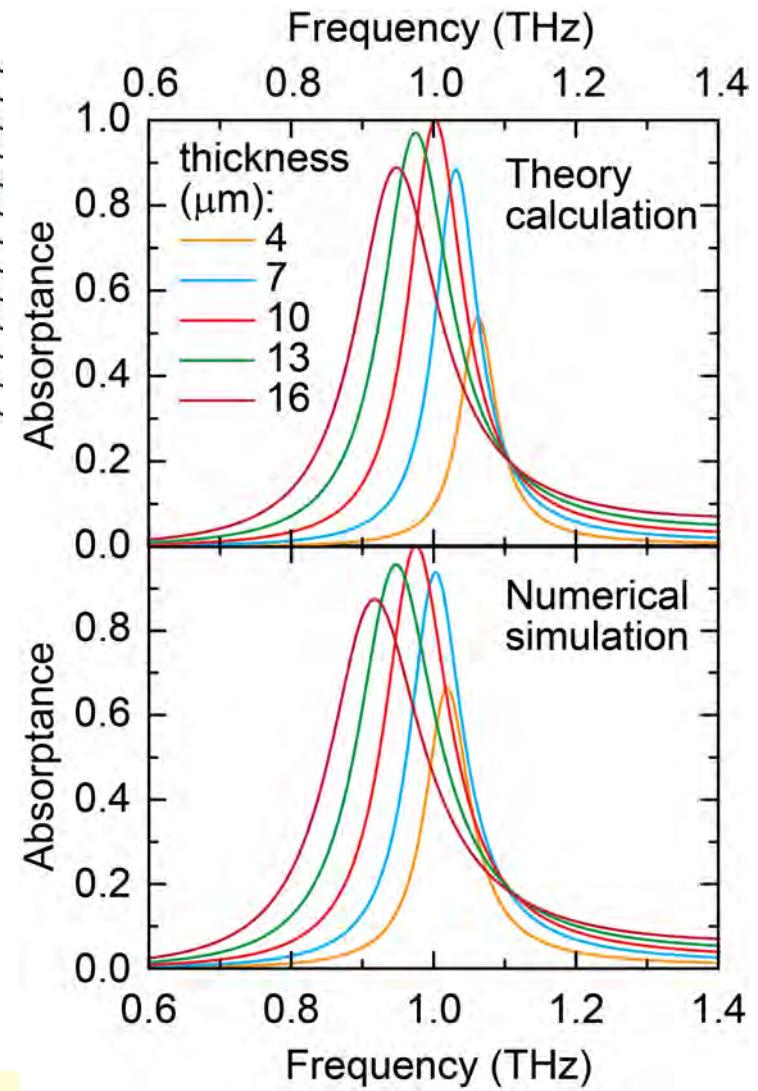
- ❑ Additional sample fabrication and measurements are going on

# Metamaterial Perfect Absorbers: Trapped Light



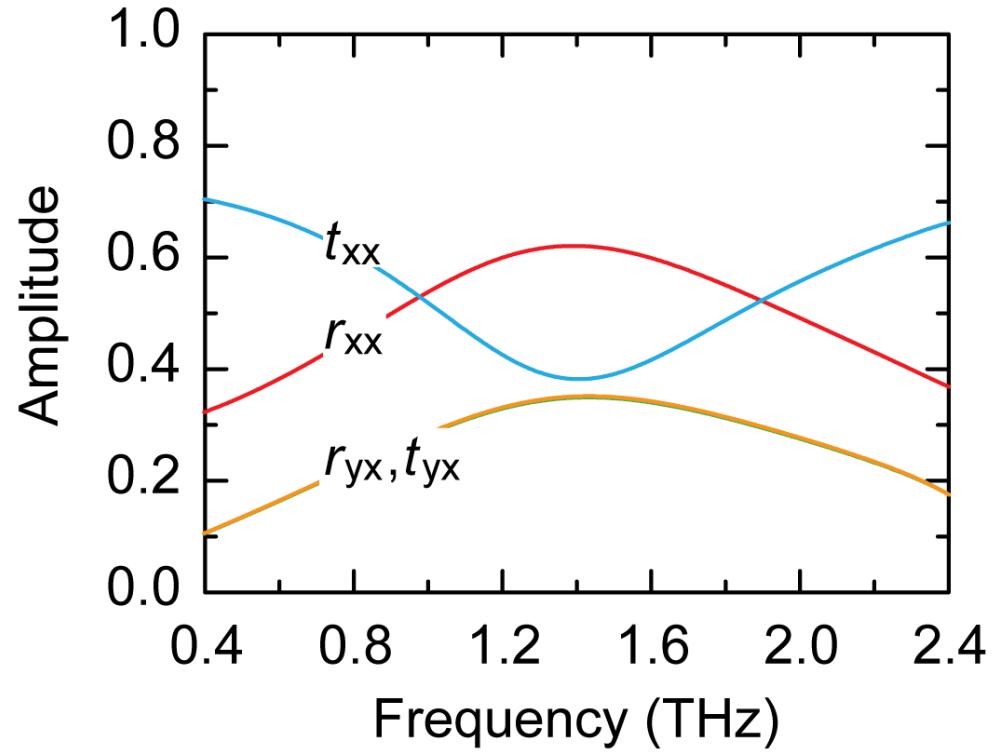
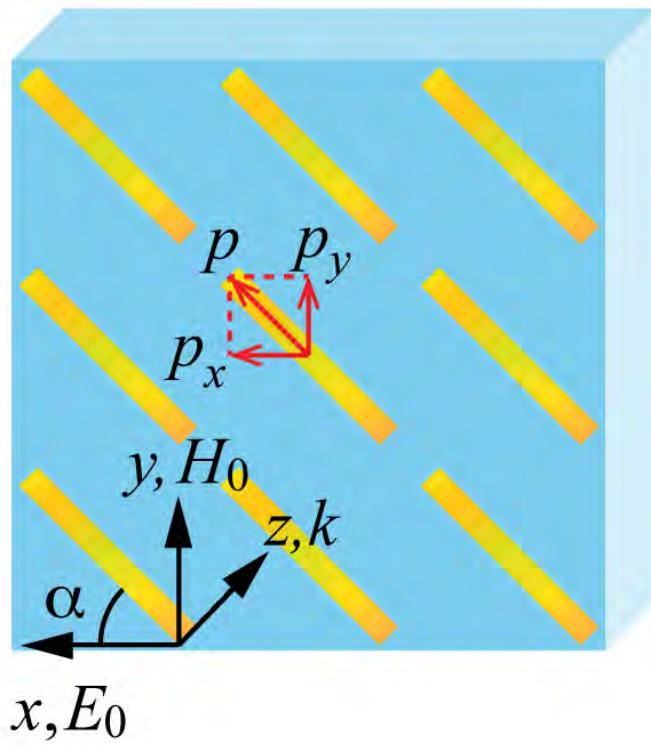
$$\tilde{r} = \tilde{r}_{12} + \frac{\tilde{t}_{12} \tilde{t}_{21} \tilde{r}_{23} e^{i2\tilde{\beta}}}{1 - \tilde{r}_{21} \tilde{r}_{23} e^{i2\tilde{\beta}}}$$

- Zero transmission due to the metal ground plane
- Minimizing reflection due to destructive interference of multi-reflection
- Absorptance:  $A = 1 - R$



*Opt. Express* 20, 7165 (2012).  
*Appl. Phys. Lett.* 101, 101102 (2012).

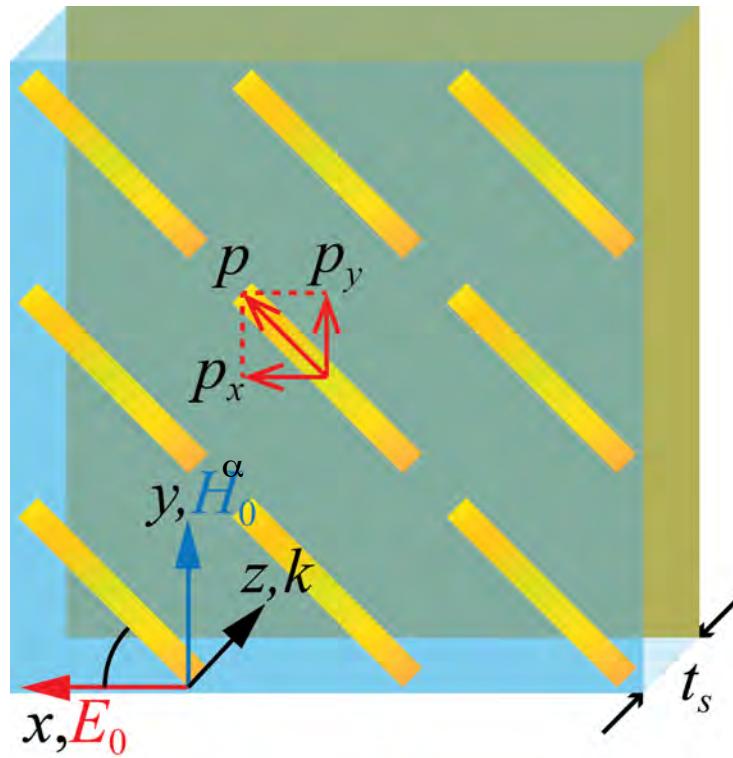
# Anisotropic Metasurfaces



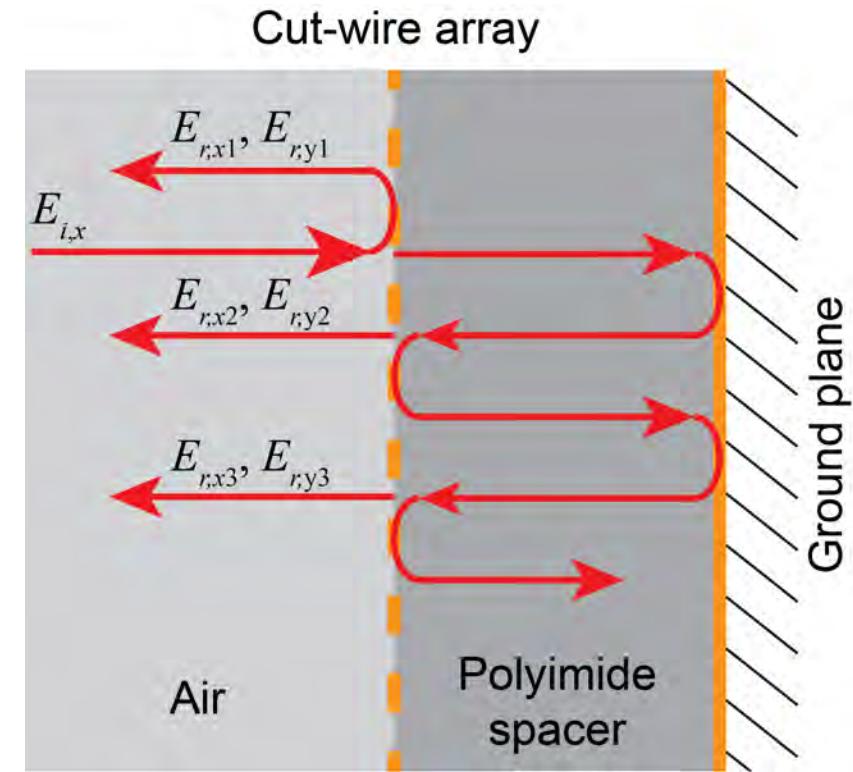
- Incident field  $E_0$  along  $x$ -direction ( $\alpha=45^\circ$ ): the excited dipole  $p$  has  $x$ - and  $y$ -components
- Single-layer metasurface:: Output waves are elliptically polarized

# Reflective Linear Polarization Converter

## Structure schematics

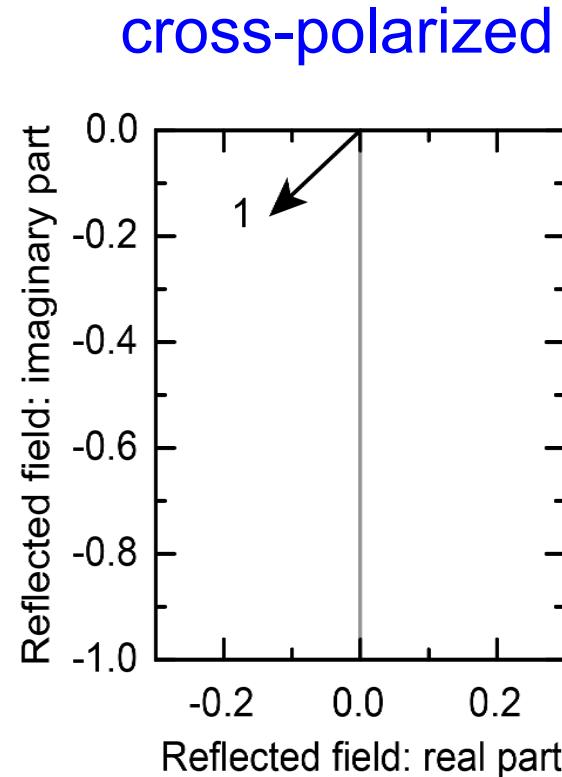
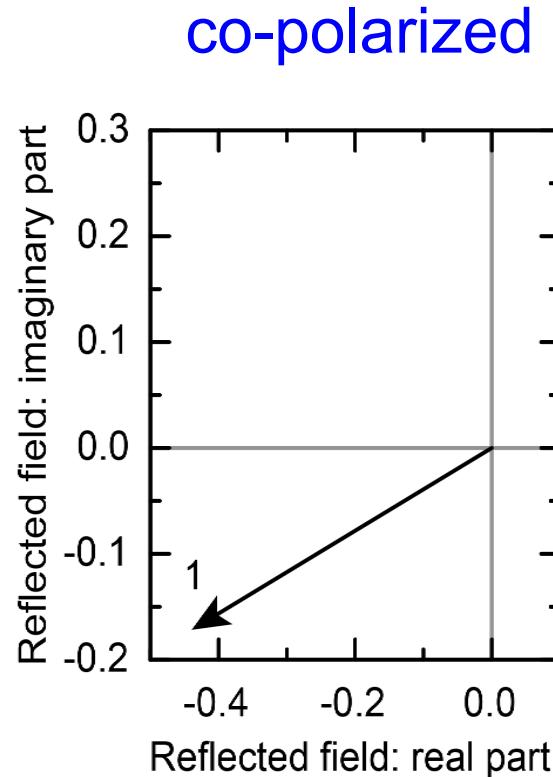
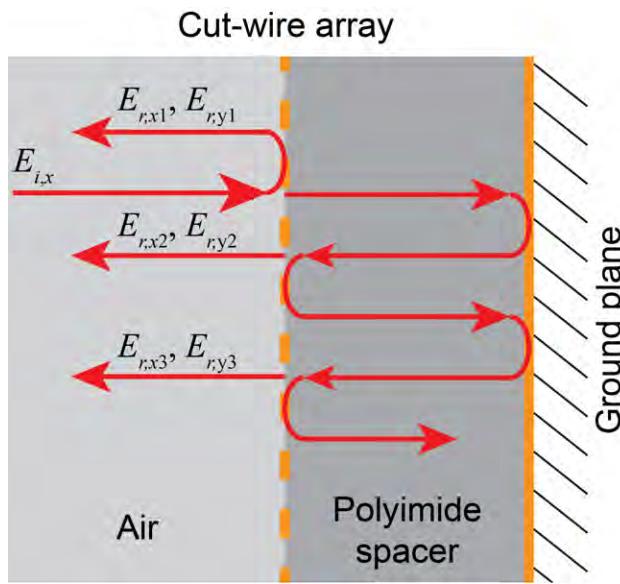


## Multireflection and conversion



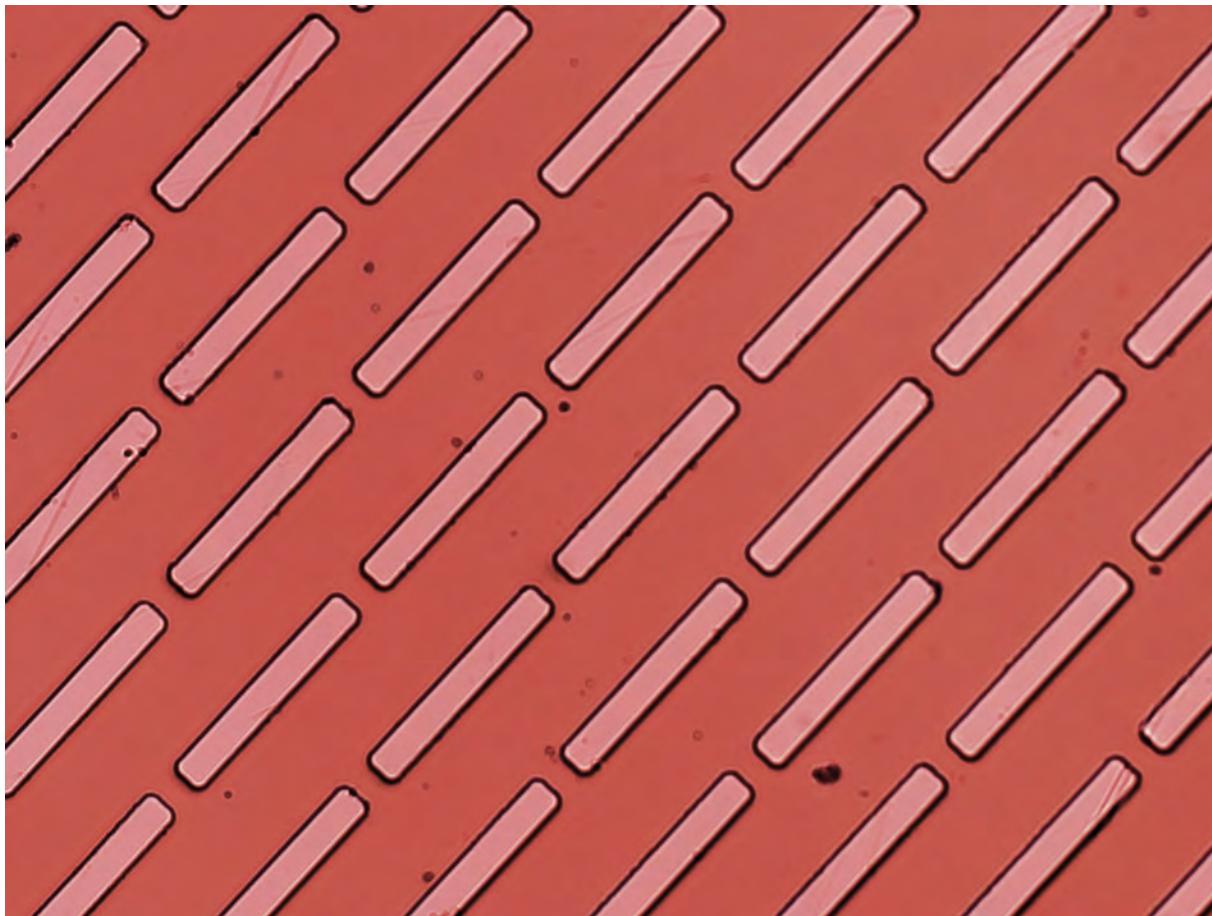
# Reflective Linear Polarization Converter

## Constructive and destructive interferences

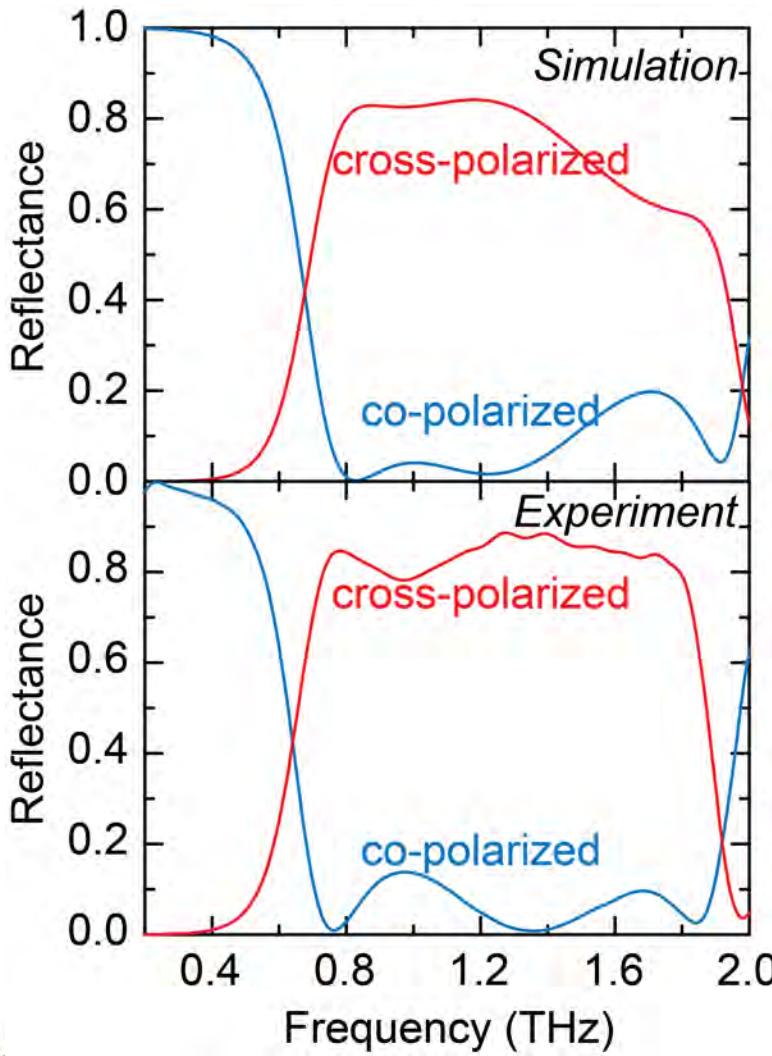


# Reflective Linear Polarization Converter

Optical microscopy image



# Reflective Linear Polarization Converter

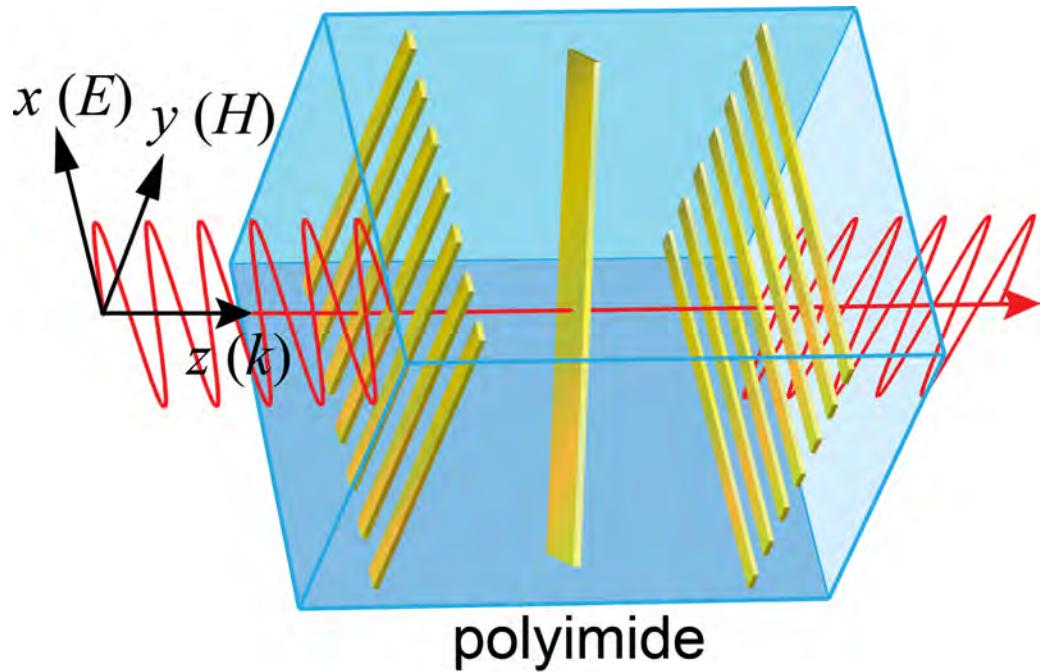


## Simulations and experiments

- Device thickness 33  $\mu\text{m}$
- Operation center wavelength 230  $\mu\text{m}$
- Co-polarized reflection is minimal
- Cross-polarized reflectance is more than 80%
- Broadband: destructive interference at multiple frequencies

# Transmission Linear Polarization Converter

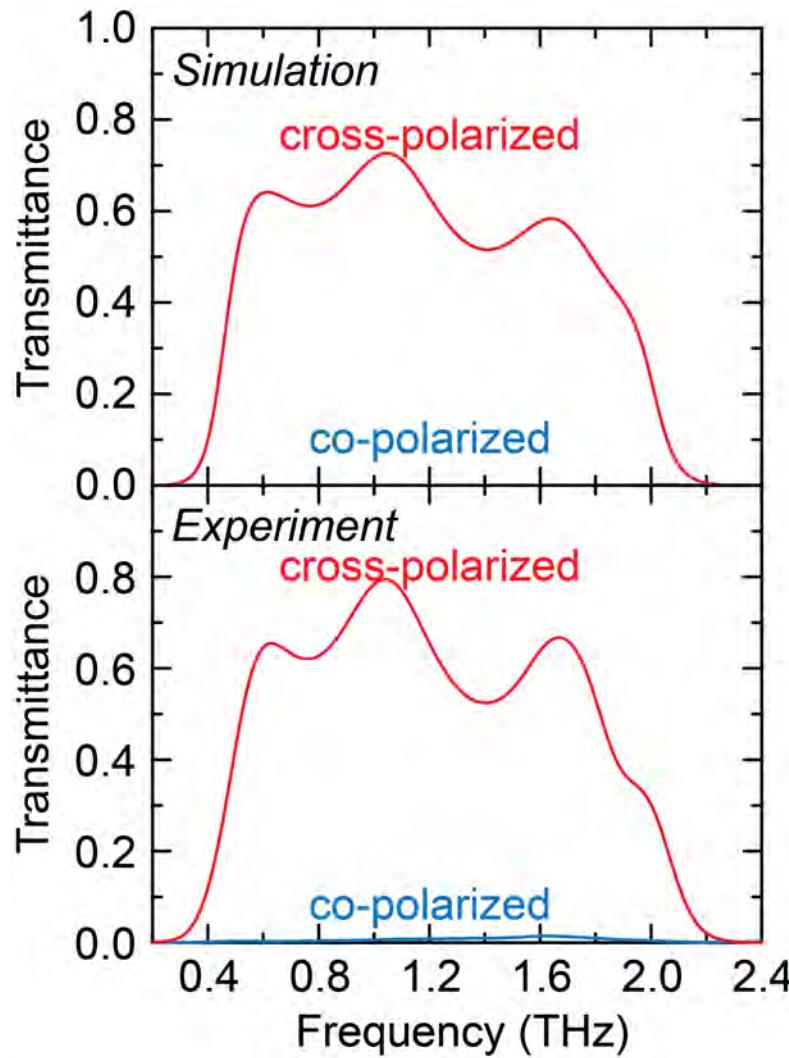
Structure schematic



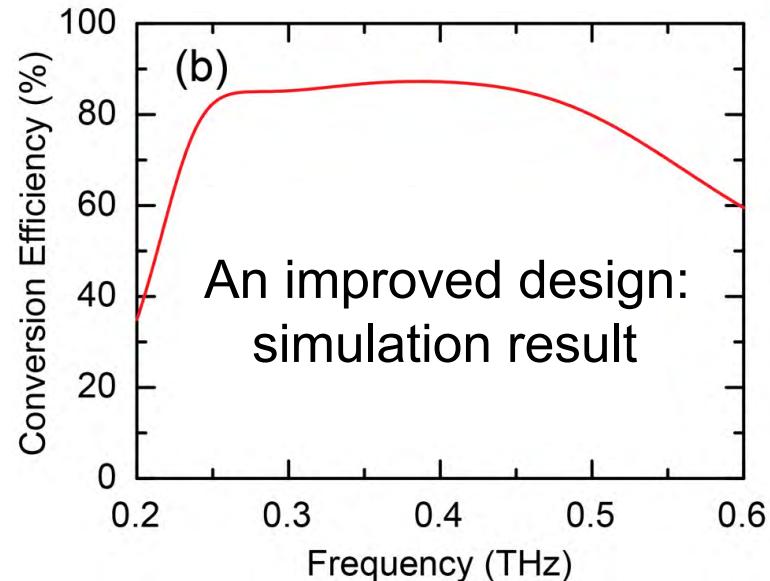
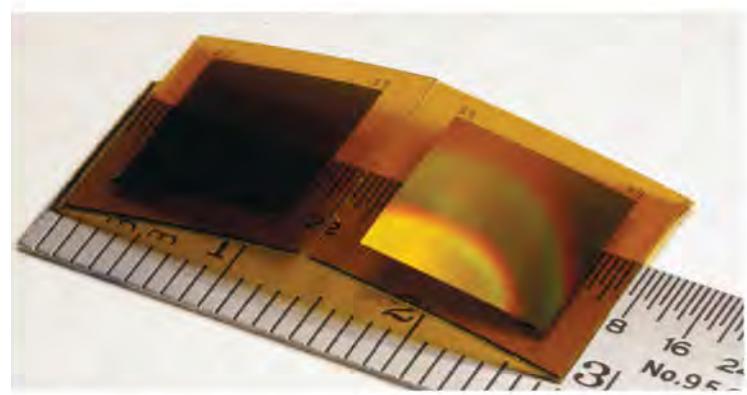
Optical microscopy image



# Transmission Linear Polarization Converter

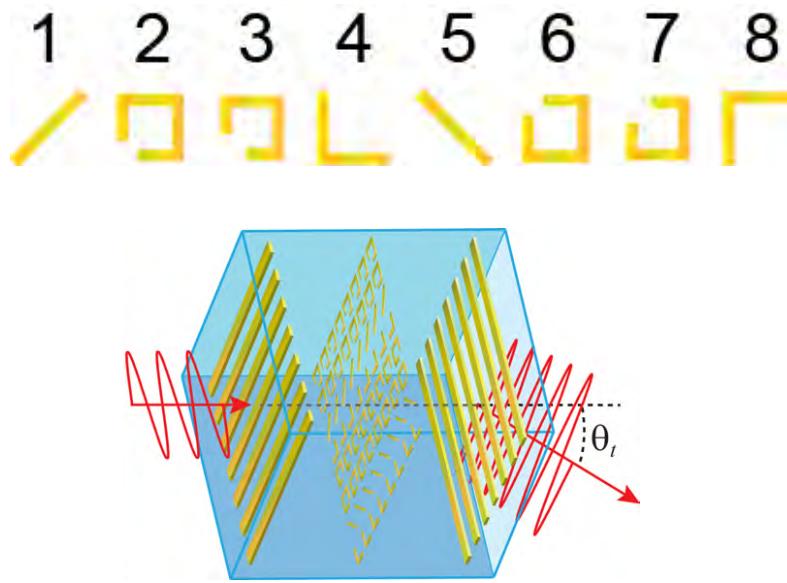


Fabricated thin film device

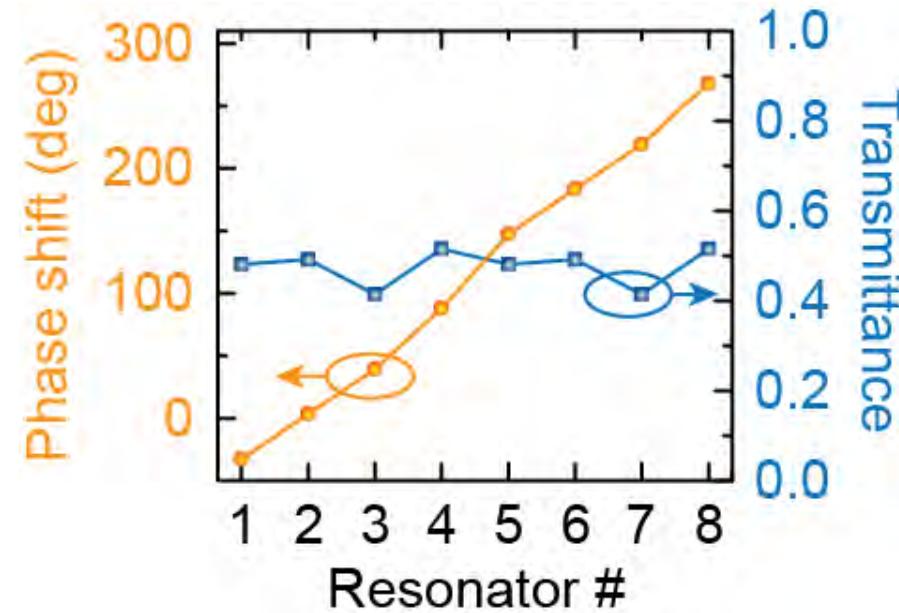


Science 340, 1304 (2013).

# Anomalous Refraction: Generalized Snell's Law



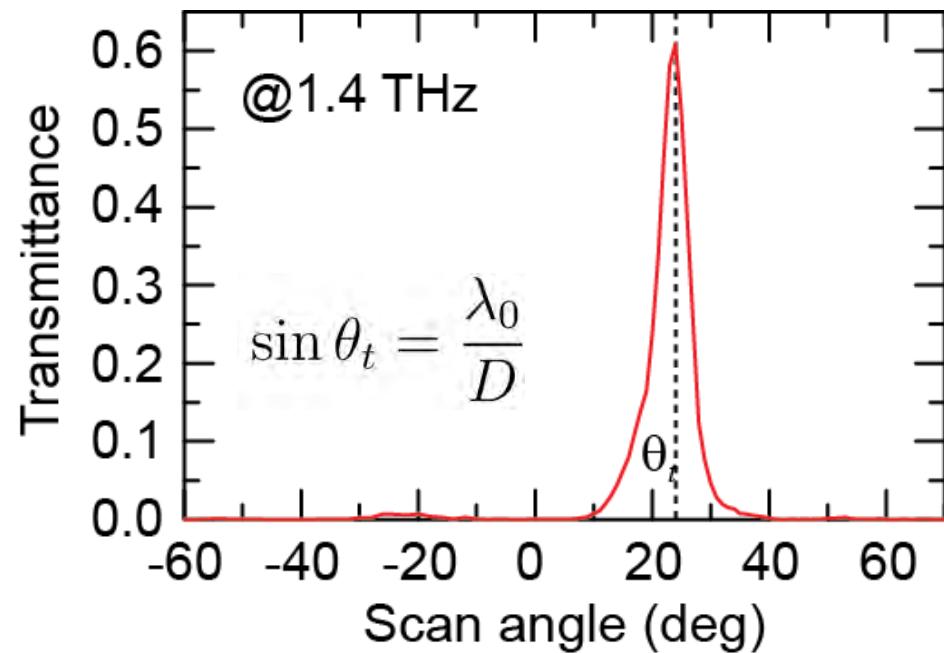
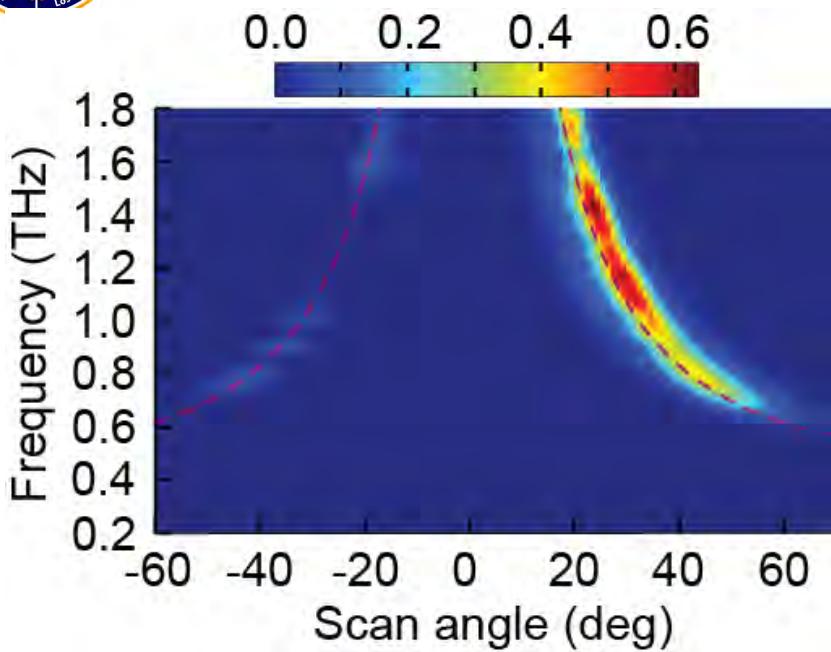
$$\sin \theta_t - \sin \theta_i = \frac{\lambda_0}{2\pi} \frac{d\Phi}{dx}$$



- Each individual element can be used in polarization converter
- Conversion efficiency is designed to be largely constant
- 8 elements form the unit cell, with a linear phase shift spanning a  $2\pi$  range

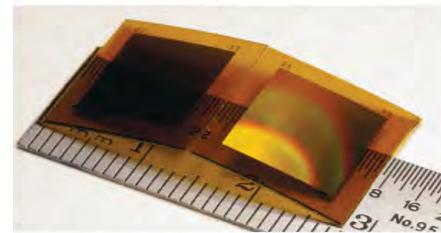
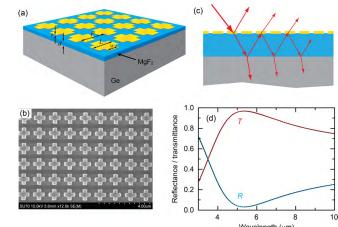
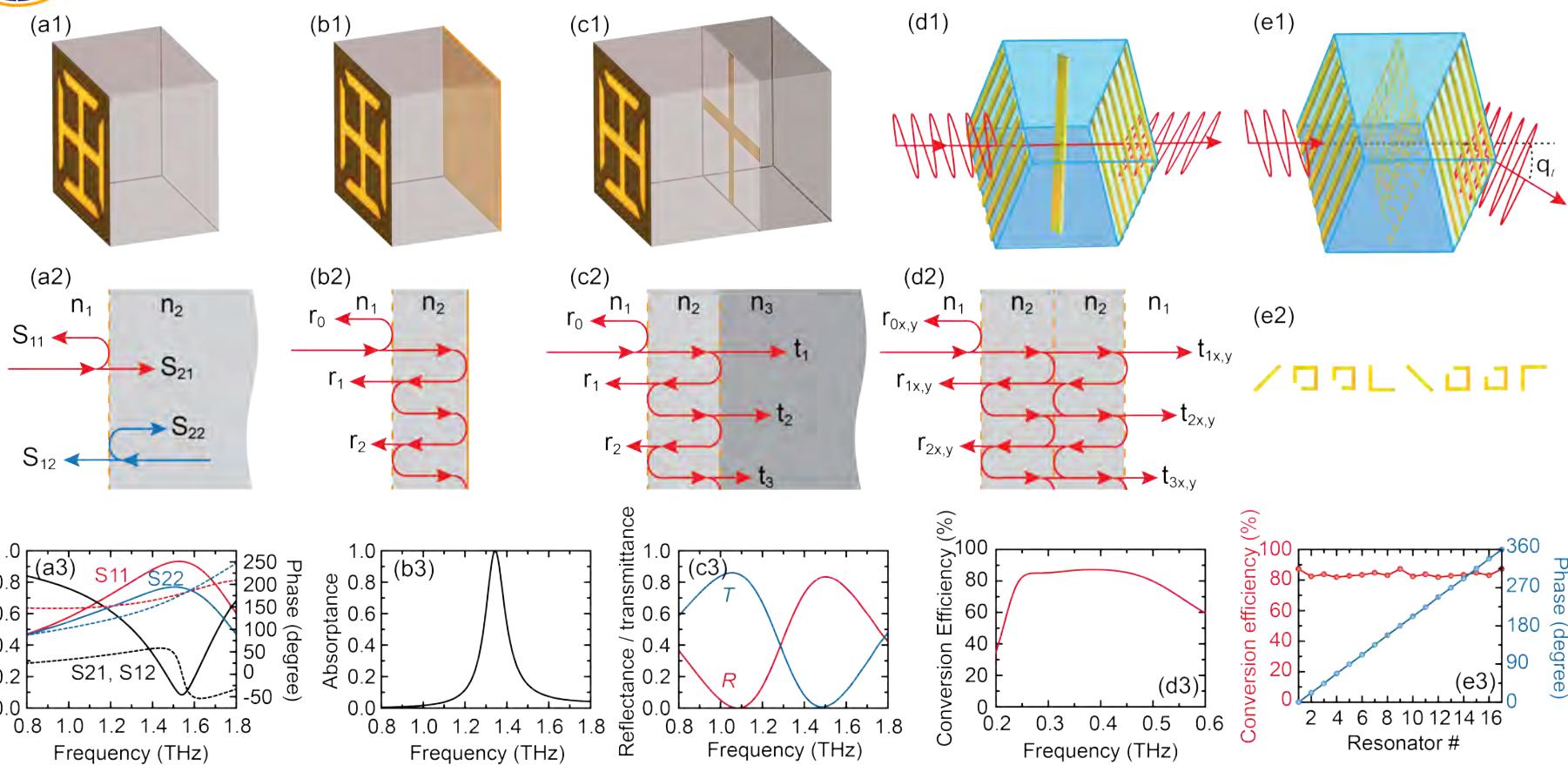
Science 340, 1304 (2013).

# Near-Perfect Anomalous Refraction: Exp.



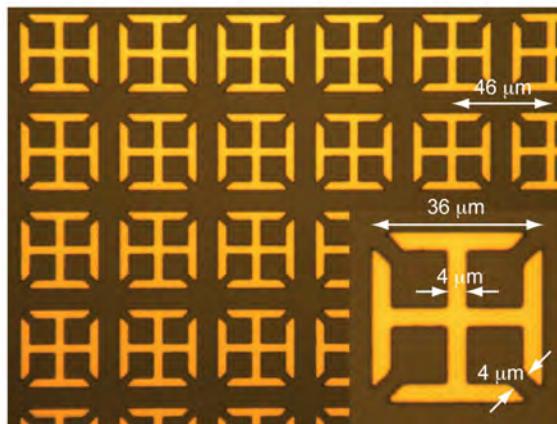
- At a specific frequency, the “refraction angle” is determined by periodicity
- At 1.4 THz, the anomalous refraction carries 60% of the incident power
- Measure the cross-polarized transmission vs. scanning angle
- Operate over a broad bandwidth

# Summary of Few-Layer Metamaterials (Metasurfaces)

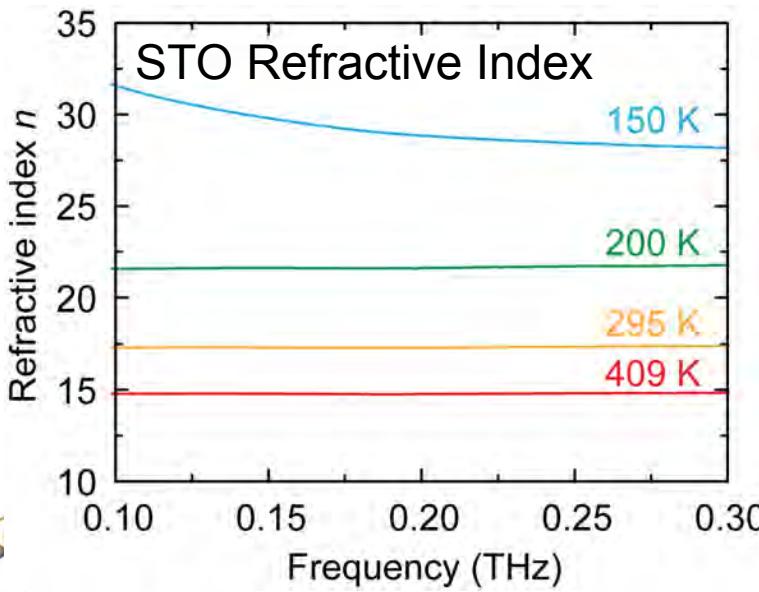


# Thermally Tunable Metasurface Resonance

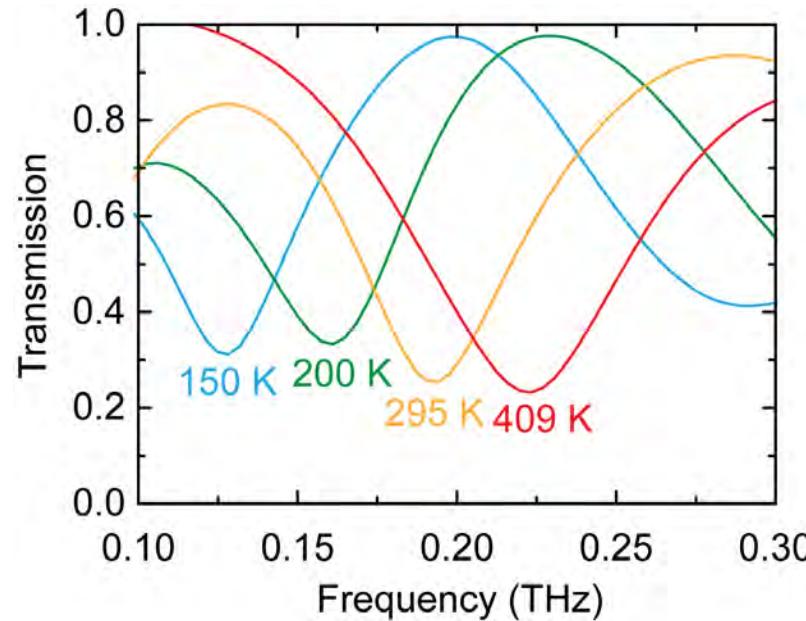
Strontium Titanate Substrate



$$\omega_0 = 1/\sqrt{LC} \sim 1/n$$



- Fabrication: photolithography, e-beam metal deposition, and lift-off process
- Substrate: silicon, gallium arsenide, etc.
- Resonance frequency tuning using strontium titanate (STO) substrate



*Opt. Lett. 36, 1230 (2011).*

# Optically Switchable THz Metamaterials

GaAs substrate

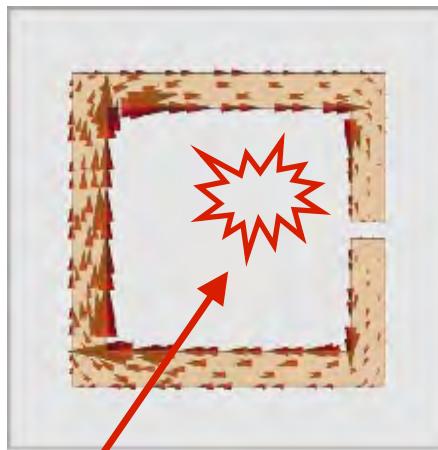
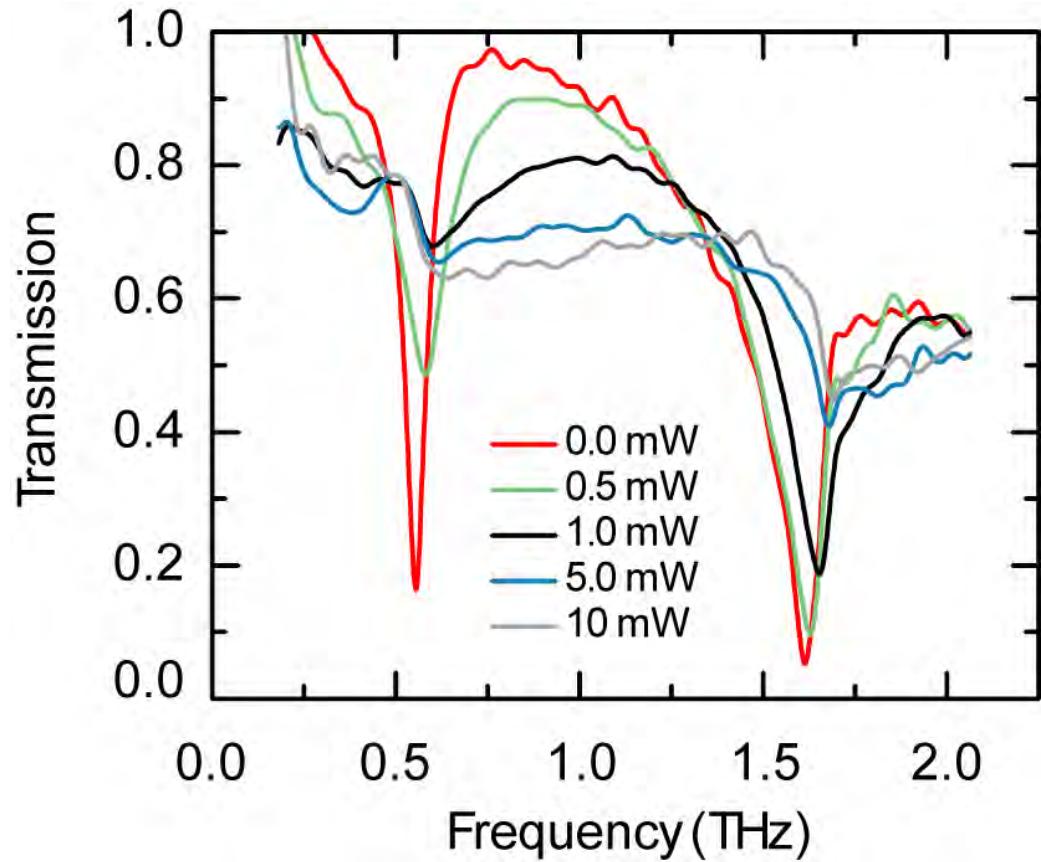
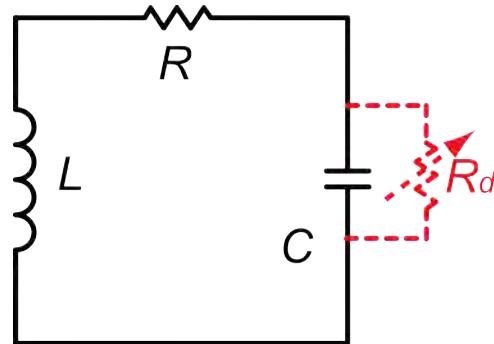
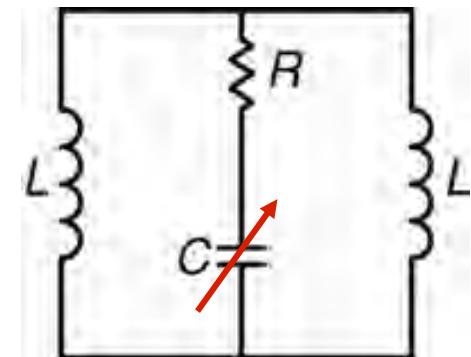
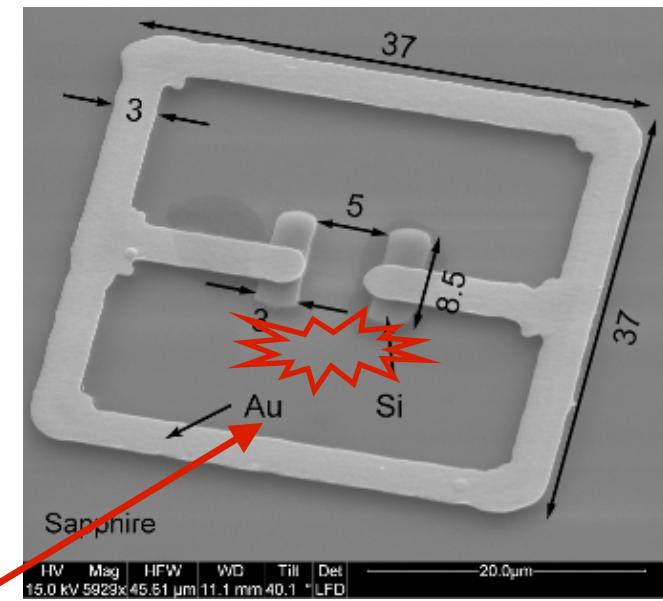
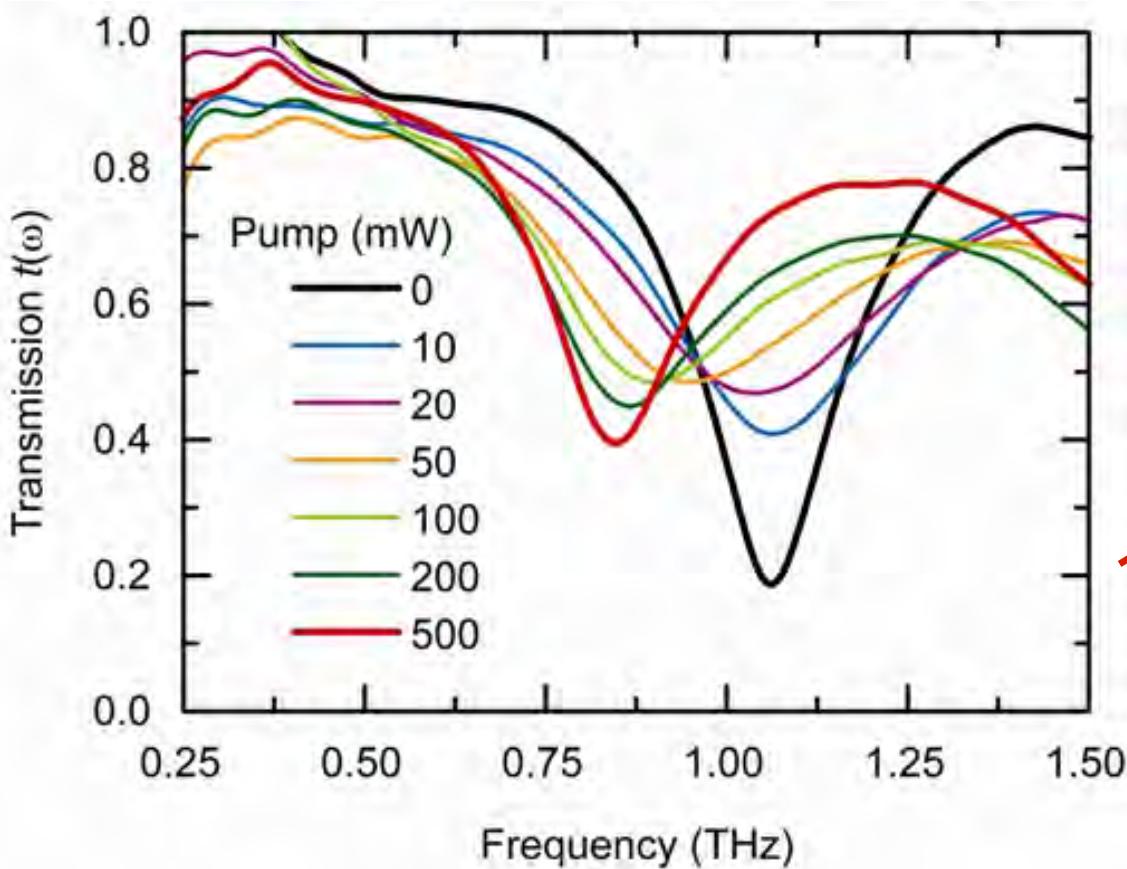


photo-excitation



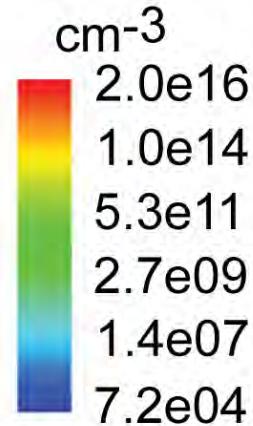
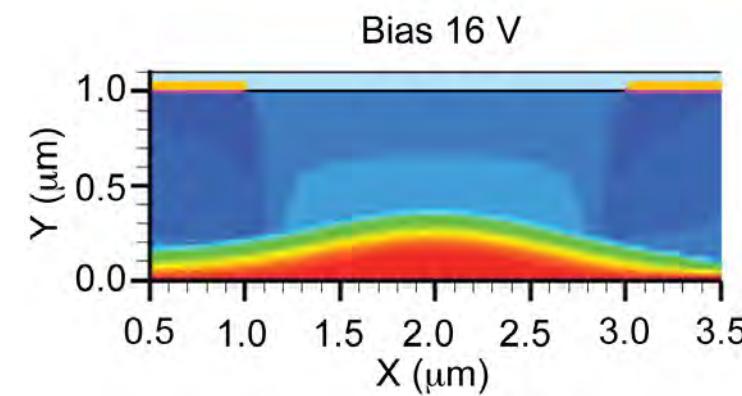
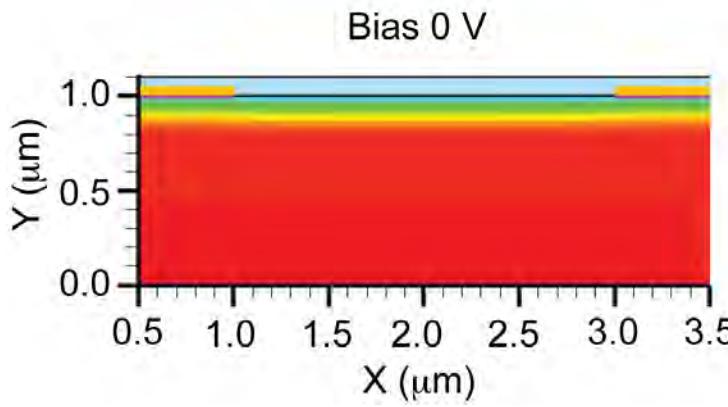
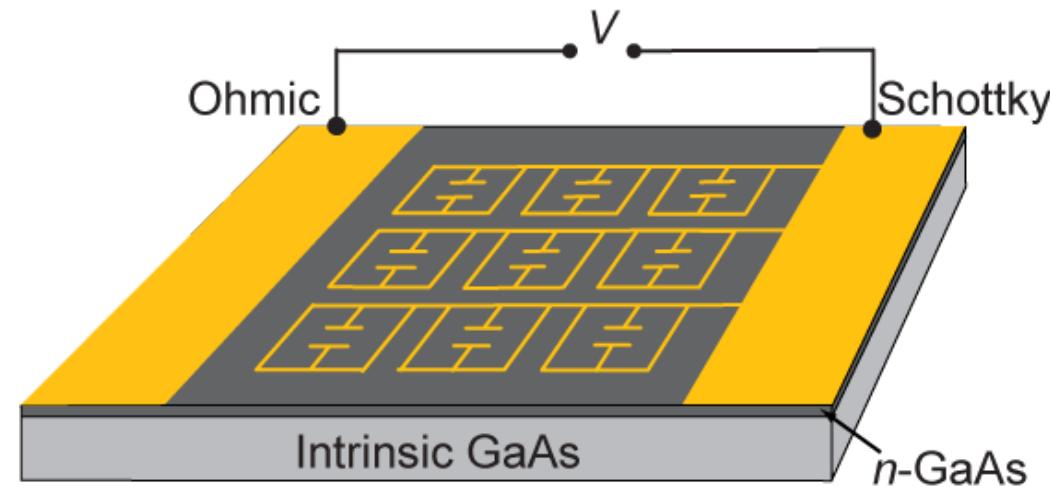
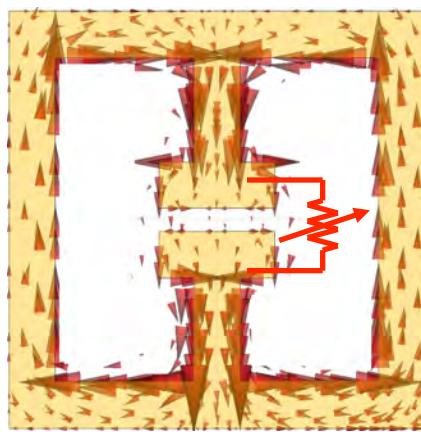
*Phys. Rev. Lett.* **96**, 107401 (2006).  
*Opt. Lett.* **32**, 1620 (2007).

# Optically Frequency Tunable THz Metamaterials



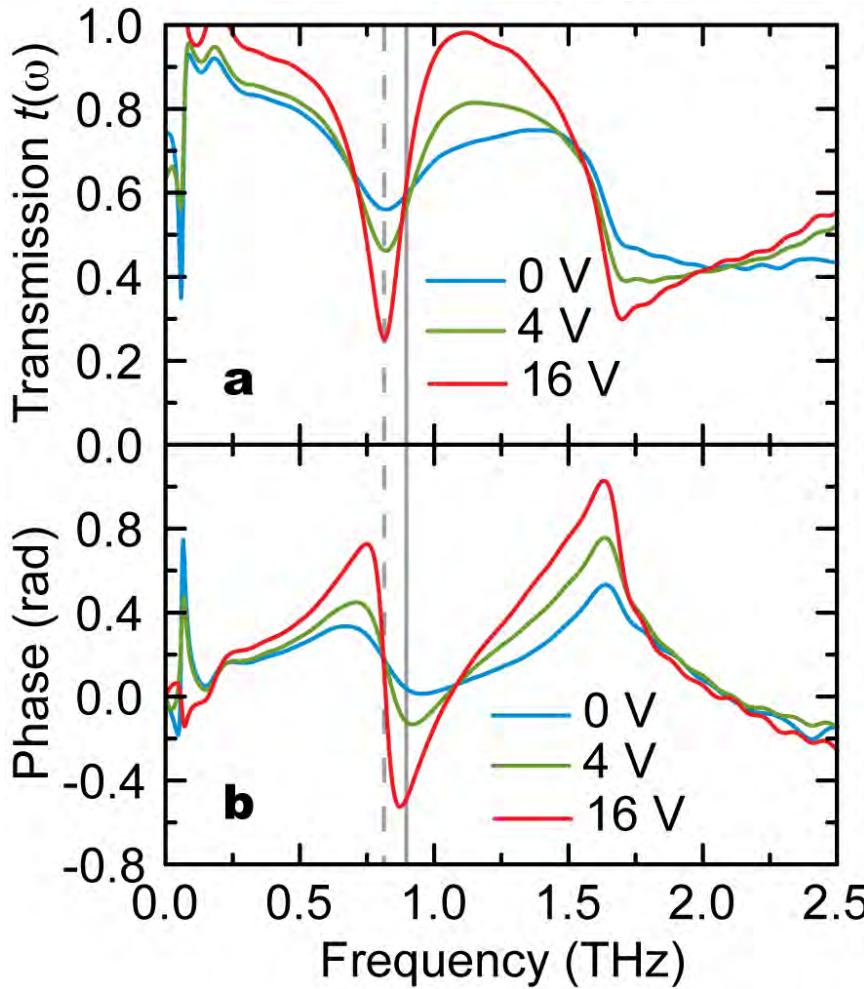
*Nat. Photon.* 2, 295 (2008).

# Electrically Switchable THz Metamaterials



*Nature* 444, 597 (2006).

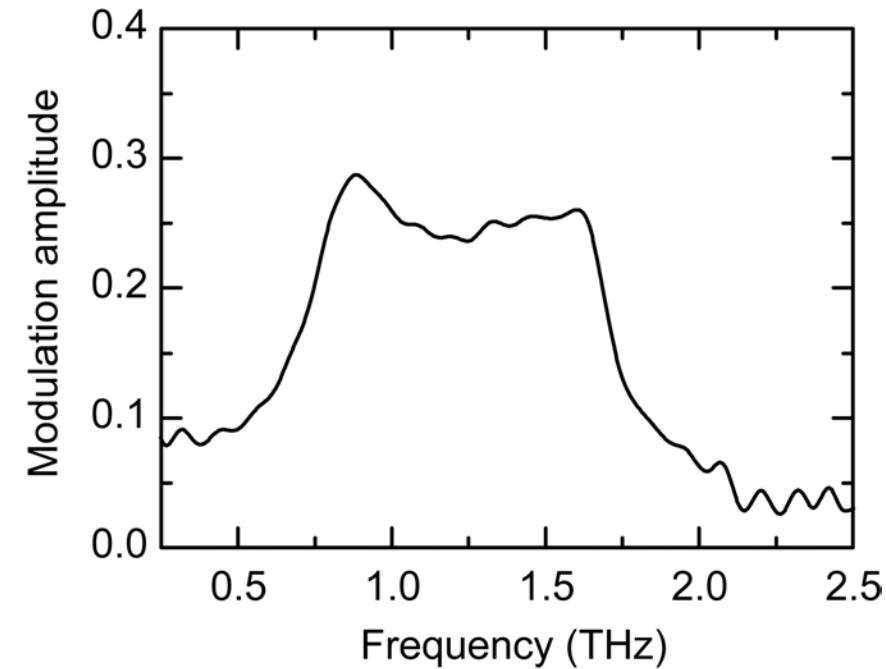
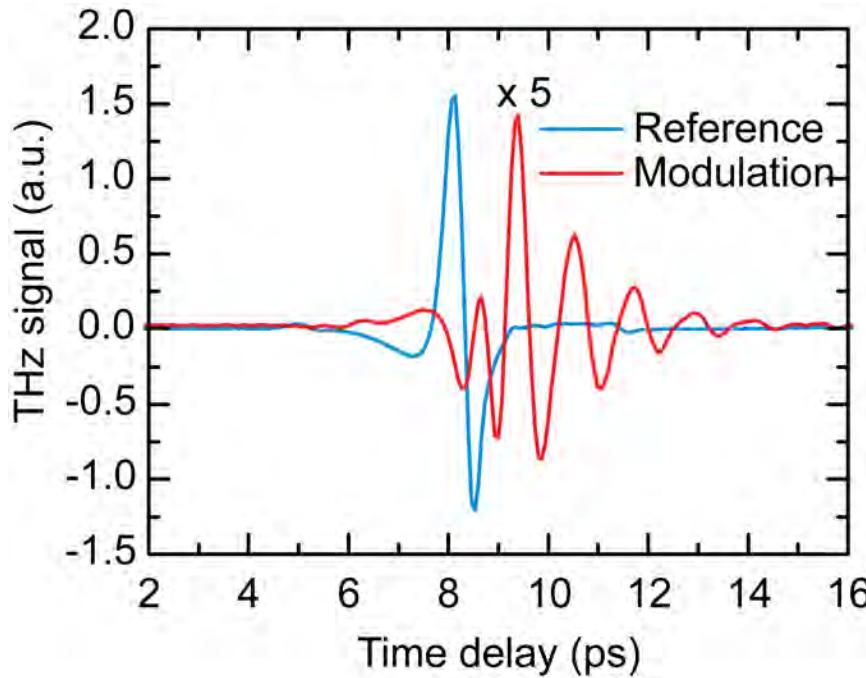
# Amplitude and Phase Modulations



- Power modulation depth:  $M = (T_{0V} - T_{16V}) / T_{0V} = 80\%$ , or amplitude modulation depth 55%
- Phase modulation  $\Delta\phi = \pi/6$
- Amplitude and phase modulations are correlated
- In THz-TDS, both amplitude and phase contribute to the modulation signal – **broadband modulation**

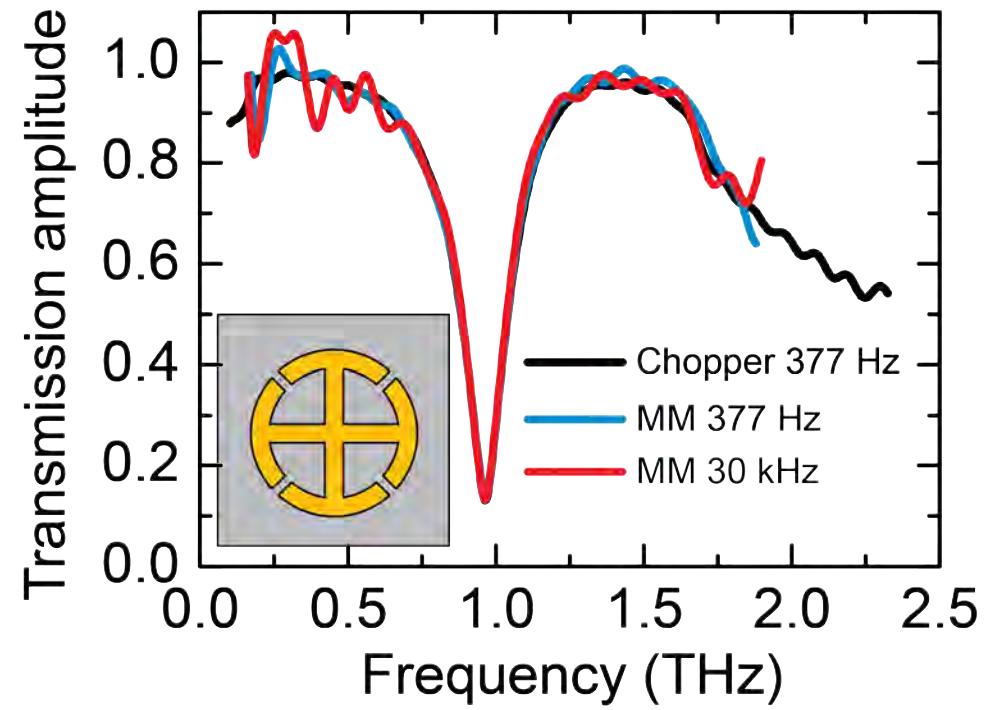
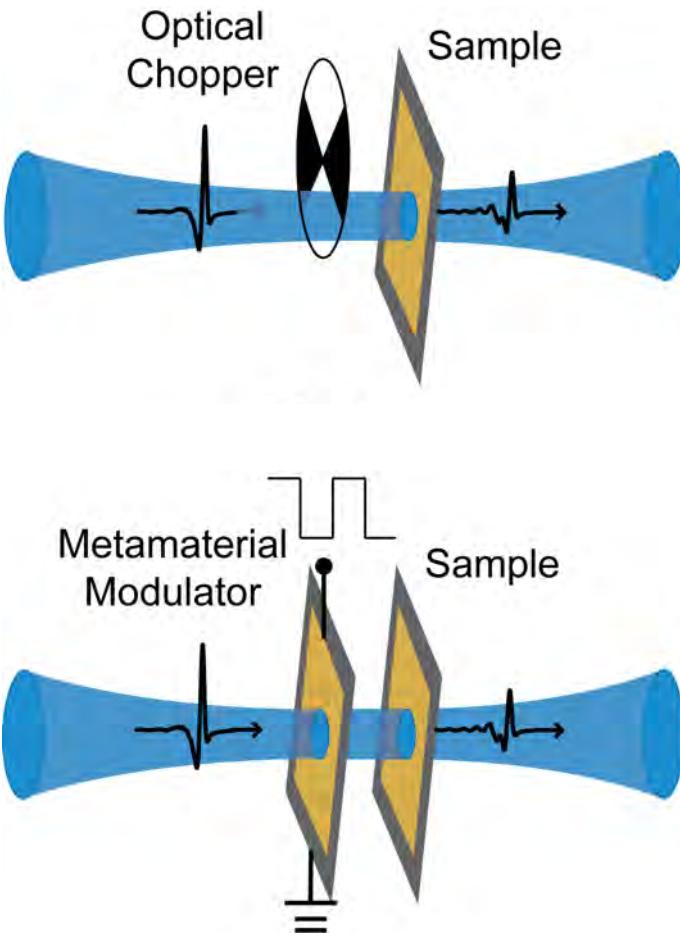
$$|\tilde{\Delta t}(\omega)| = \left| t_{V1}(\omega) e^{i\phi_{V1}(\omega)} - t_{V2}(\omega) e^{i\phi_{V2}(\omega)} \right|$$

# Broaden the Modulation Bandwidth



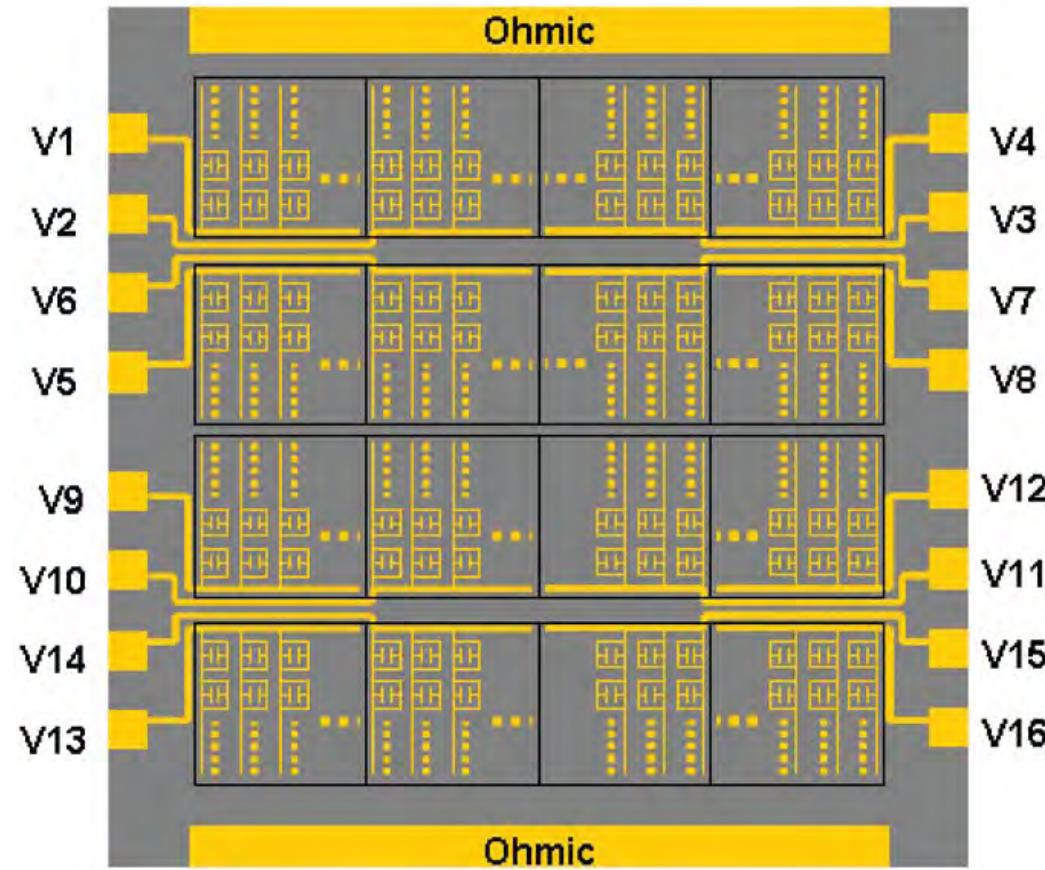
**Bandwidth:** roughly between the two resonances

# Serving as the Optical Chopper in THz-TDS



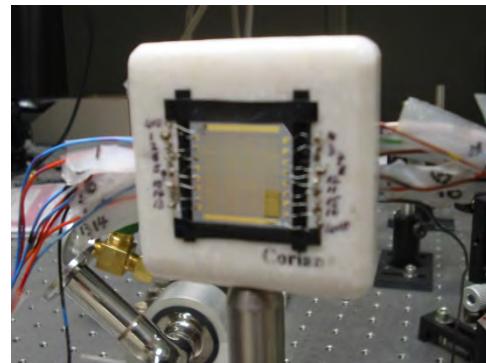
*Nat. Photon.* 3, 148 (2009).

# THz Metamaterial Spatial Light Modulator



$4 \times 4$  pixels, each pixel is independently controlled by voltage bias

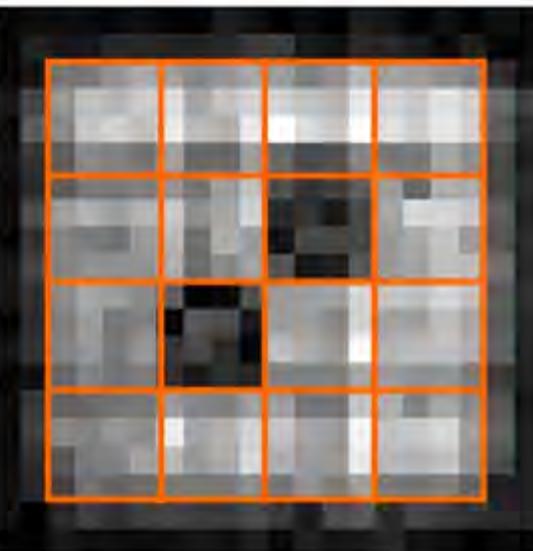
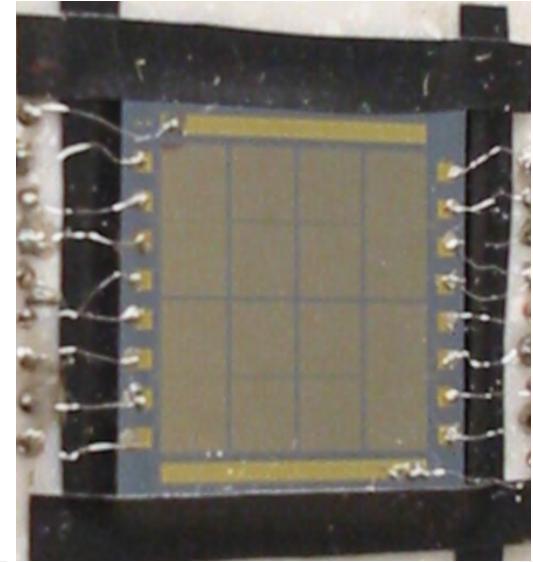
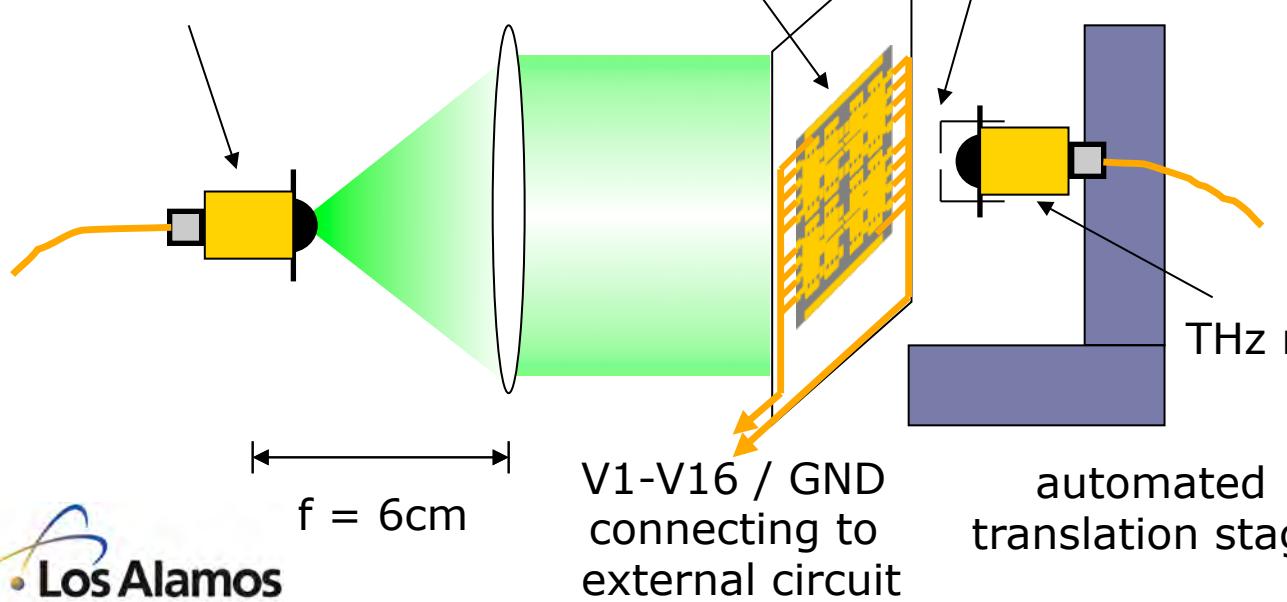
# THz Metamaterial Spatial Light Modulator



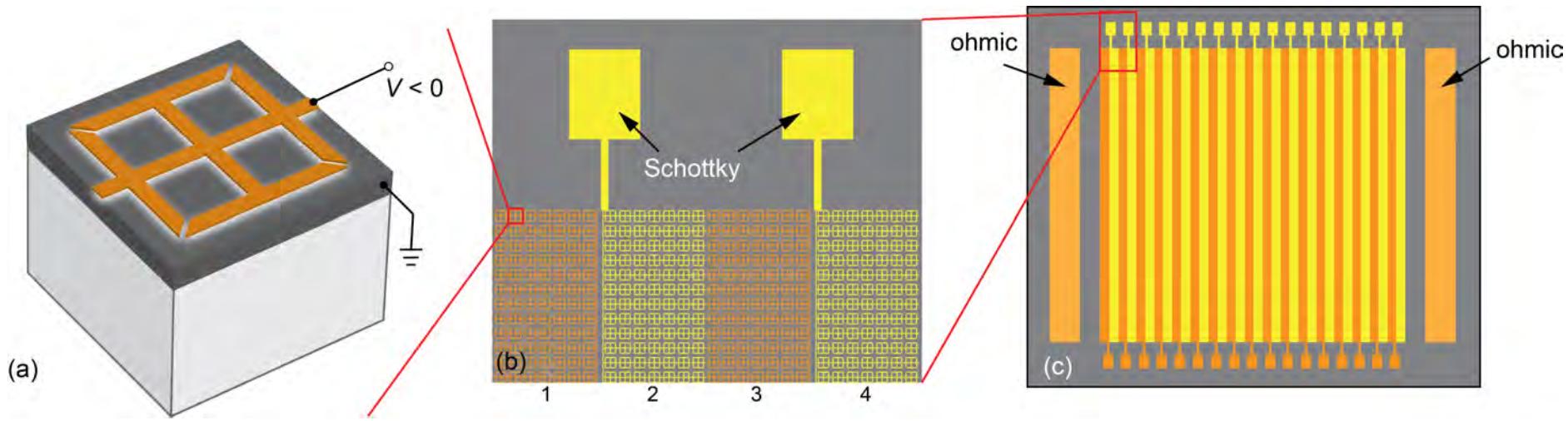
THz transmitter  
(fiber-coupled  
PC antenna)

THz spatial  
modulator

metal  
aperture

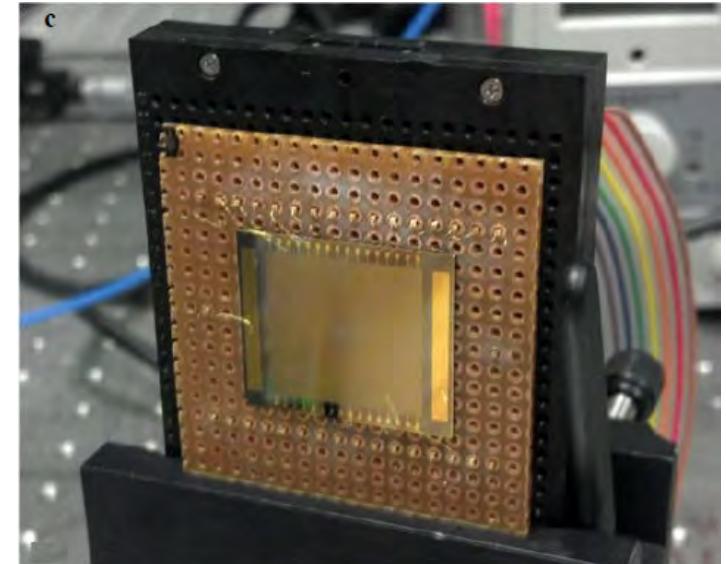
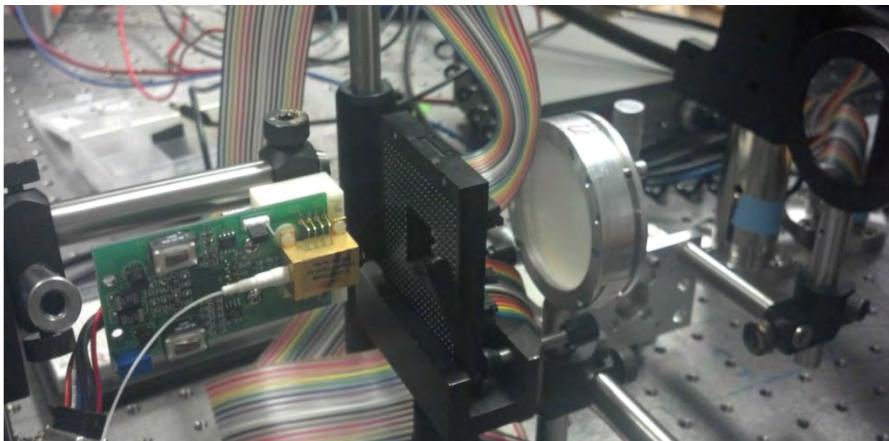
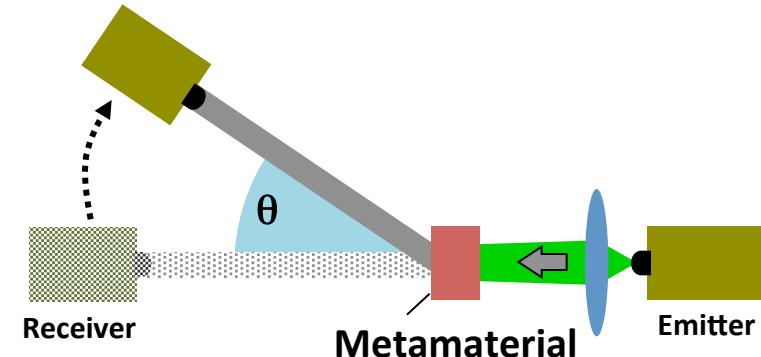


# Active Metamaterial Gratings

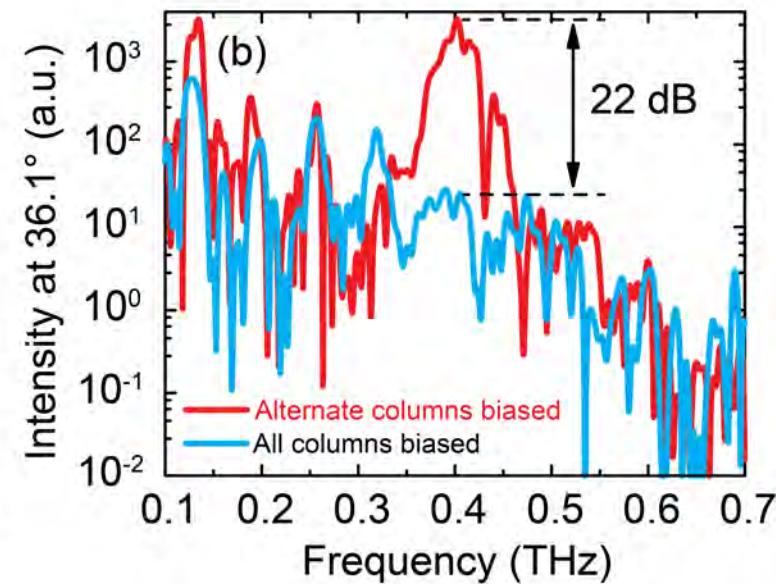
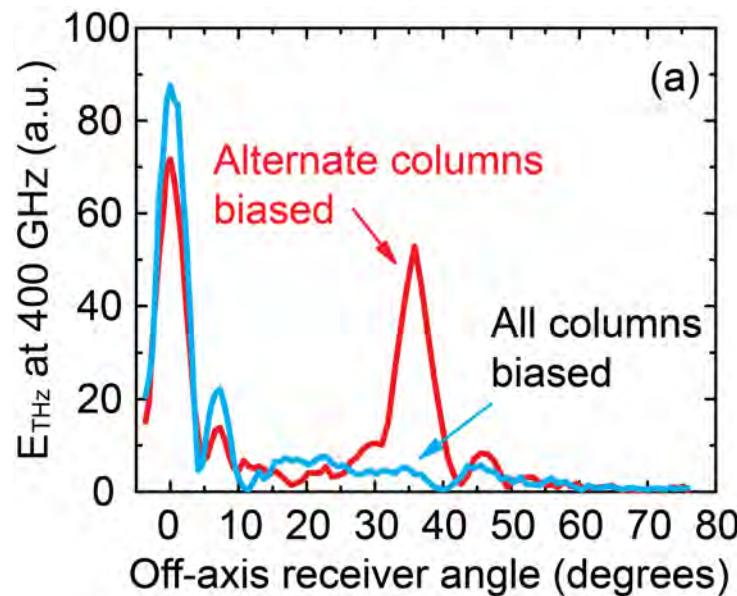


# Active Metamaterial Gratings -- Experiment

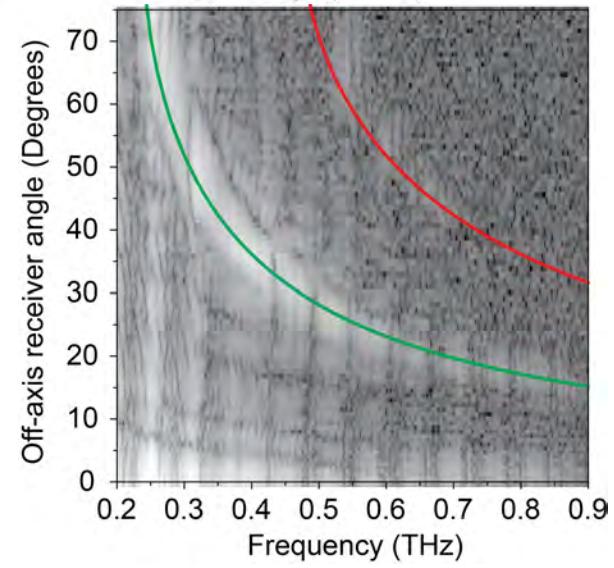
- Broadband THz system
- Collimated beam incident on metamaterial surface
- Detect transmitted beam at different angles



# Active Metamaterial Gratings -- Results

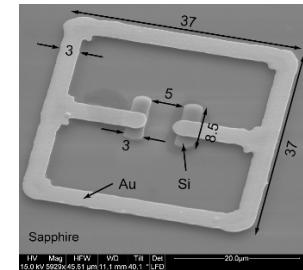
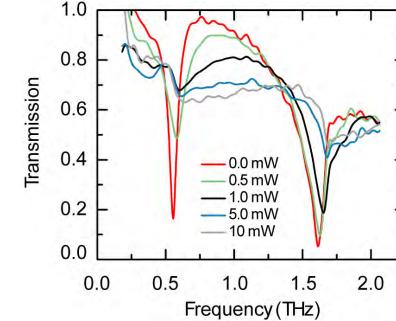
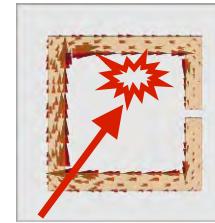
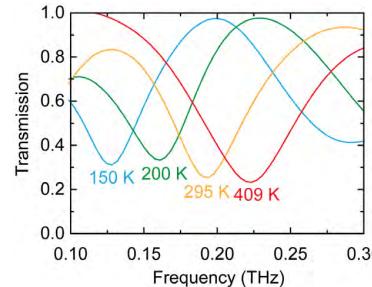
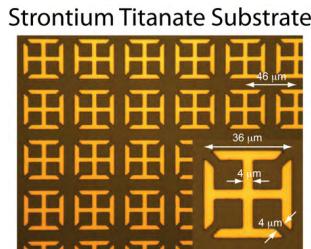


- Switchable grating diffraction
- 22 dB modulation depth
- Broadband operation
- Background-free in principle

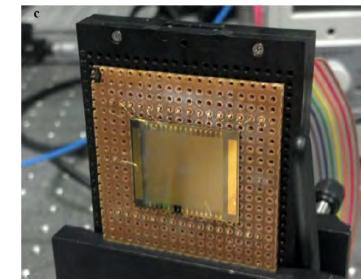
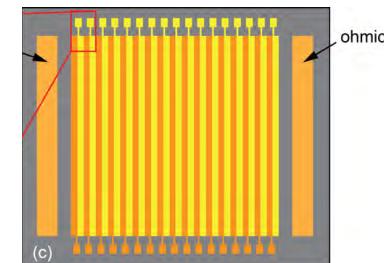
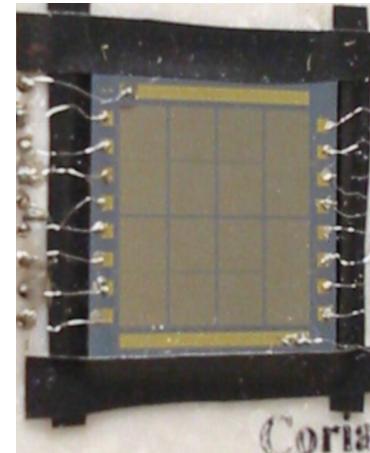
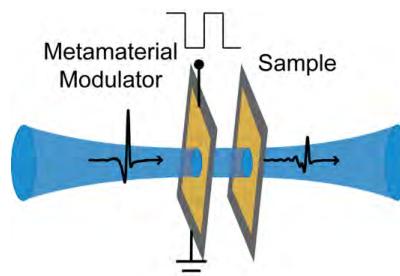
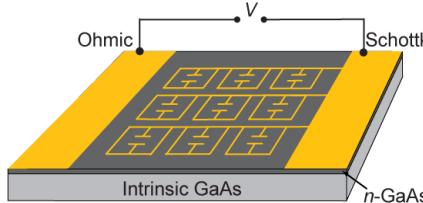


# Summary of Active Metamaterials/Metasurfaces

- Switchable and frequency tunable resonant response in single-layer metasurfaces by active material integration and external excitation



- Electrically switchable metasurface as THz signal modulator for imaging and communication





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BU/UCSD: Richard Averitt

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UCB: Xiang Zhang

Nankai: Shuqi Chen, Jianguo Tian

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